













ADC12D1800

SNAS500Q - MAY 2010 - REVISED MAY 2017

# ADC12D1800 12-Bit, Single 3.6 GSPS Ultra High-Speed ADC

### 1 Device Overview

#### 1.1 Features

- Configurable to Either 3.6 GSPS Interleaved or 1.8 GSPS Dual ADC
- Pin-Compatible with ADC10D1000/1500 and ADC12D1000/1600
- Internally Terminated, Buffered, Differential Analog Inputs
- Interleaved Timing Automatic and Manual Skew Adjust
- · Test Patterns at Output for System Debug
- Programmable 15-bit Gain and 12-bit Plus Sign Offset
- Programmable t<sub>AD</sub> Adjust Feature
- 1:1 Non-Demuxed or 1:2 Demuxed LVDS Outputs
- AutoSync Feature for Multi-Chip Systems
- Single 1.9-V ± 0.1-V Power Supply

# 1.2 Applications

- Wideband Communications
- Data Acquisition Systems
- RADAR/LIDAR

- Key Specifications
  - Resolution: 12 Bits
  - Interleaved 3.6 GSPS ADC
    - Noise Floor Density –153.5 dBm/Hz (typ)
    - IMD3 –61 dBFS (typ)
    - Noise Power Ratio 48.5 dB (typ)
    - Power 4.4 W (typ)
    - Full Power Bandwidth 1.75 GHz (typ)
  - Dual 1.8 GSPS ADC, Fin = 125MHz
    - ENOB: 9.4 (typ)
    - SNR 58.5 dB (typ)
    - SFDR 73 dBc (typ)
    - Power 4.4 W (typ)
    - Full Power Bandwidth 2.8 GHz (typ)
- · Set-top Box
- Consumer RF
- Software Defined Radio

# 1.3 Description

The 12-bit, 3.6 GSPS ADC12D1800 is the latest advance in TI's Ultra-High-Speed ADC family and builds upon the features, architecture and functionality of the 10-bit GHz family of ADCs.

The ADC12D1800 provides a flexible LVDS interface which has multiple SPI programmable options to facilitate board design and FPGA/ASIC data capture. The LVDS outputs are compatible with IEEE 1596.3-1996 and supports programmable common mode voltage.

The product is packaged in a leaded or lead-free 292-ball thermally enhanced BGA package over the rated industrial temperature range of -40°C to +85°C.

To achieve full rated performance for  $f_{CLK} > 1.6$  GHz, write the maximum power settings one time to Register 6h through the serial interface; see Section 5.6.1 for more information.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
ADC12D1800	BGA (292)	27.00 mm × 27.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



# 1.4 Functional Block Diagram

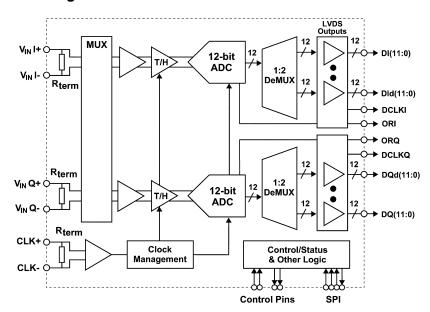


Figure 1-1. Functional Block Diagram



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2	Rev	rision History NOTE: Page numbers for previous revision	s ma	y differ	from <sub>l</sub>	page numbers in the current version.	
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	• CI	hanged cross-reference in last paragraph of Des	script	ion sect	ion to	point to correct section	. <u>1</u>
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	Fi Se	dded Pin Configuration and Functions section, Functional Modes, Application and Implementation ection, Device and Documentation Support section	n sec on, a	tion, Pond nd Mec	ower S hanica	Supply Recommendations section, Layout al, Packaging, and Orderable Information	. <u>1</u>
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•	Changed layout of National Data Sheet to TI format		54



# **Pin Configuration and Functions**

NXA Package
292-Pin BGA
Tan \/:

	1	2	3	4	5	6	7	8	9	Top-	View	12	13	14	15	16	17	18	19	20	
Α	GND	V_A	SDO	TPM	NDM	V_A	GND	V_E	GND_E	Dld0+	V_DR	Dld3+	GND_DR	Dld6+	V_DR	Dld9+	GND_DR	Dld11+	Dld11-	GND_DR	Α
В	Vbg	GND	ECEb	SDI	CalRun	V_A	GND	GND_E	V_E	DId0-	Dld2+	Dld3-	Dld5+	DId6-	Dld8+	Dld9-	Dld10+	DI0+	DI1+	DI1-	В
С	Rtrim+	Vcmo	Rext+	SCSb	SCLK	V_A	NC	V_E	GND_E	Dld1+	Dld2-	Dld4+	Dld5-	Dld7+	DId8-	Dld10-	DI0-	V_DR	DI2+	DI2-	С
D	DNC	Rtrim-	Rext-	GND	GND	CAL	DNC	V_A	V_A	Dld1-	V_DR	DId4-	GND_DR	Dld7-	V_DR	GND_DR	V_DR	DI3+	DI4+	DI4-	D
Е	V_A	Tdiode+	DNC	GND													GND_DR	DI3-	DI5+	DI5-	Е
F	V_A	GND_TC	Tdiode-	DNC													GND_DR	DI6+	DI6-	GND_DR	F
G	V_TC	GND_TC	V_TC	V_TC													DI7+	DI7-	DI8+	DI8-	G
Н	VinI+	V_TC	GND_TC	V_A				GND	GND	GND	GND	GND	GND				DI9+	DI9-	DI10+	DI10-	Н
J	Vinl-	GND_TC	V_TC	Vbiasl				GND	GND	GND	GND	GND	GND				V_DR	DI11+	DI11-	V_DR	J
K	GND	VbiasI	V_TC	GND_TC				GND	GND	GND	GND	GND	GND				ORI+	ORI-	DCLKI+	DCLKI-	K
L	GND	VbiasQ	V_TC	GND_TC				GND	GND	GND	GND	GND	GND				ORQ+	ORQ-	DCLKQ+	DCLKQ-	L
М	VinQ-	GND_TC	V_TC	VbiasQ				GND	GND	GND	GND	GND	GND				GND_DR	DQ11+	DQ11-	GND_DR	M
N	VinQ+	V_TC	GND_TC	V_A				GND	GND	GND	GND	GND	GND				DQ9+	DQ9-	DQ10+	DQ10-	N
Р	V_TC	GND_TC	V_TC	V_TC													DQ7+	DQ7-	DQ8+	DQ8-	Р
R	V_A	GND_TC	V_TC	V_TC													V_DR	DQ6+	DQ6-	V_DR	R
Т	V_A	GND_TC	GND_TC	GND						•				•			V_DR	DQ3-	DQ5+	DQ5-	Т
U	GND_TC	CLK+	PDI	GND	GND	RCOut1-	DNC	V_A	V_A	DQd1-	V_DR	DQd4-	GND_DR	DQd7-	V_DR	V_DR	GND_DR	DQ3+	DQ4+	DQ4-	U
٧	CLK-	DCLK _RST+	PDQ	CalDly	DES	RCOut2+	RCOut2-	V_E	GND_E	DQd1+	DQd2-	DQd4+	DQd5-	DQd7+	DQd8-	DQd10-	DQ0-	GND_DR	DQ2+	DQ2-	V
W	DCLK _RST-	GND	DNC	DDRPh	RCLK-	V_A	GND	GND_E	V_E	DQd0-	DQd2+	DQd3-	DQd5+	DQd6-	DQd8+	DQd9-	DQd10+	DQ0+	DQ1+	DQ1-	W
Υ	GND	V_A	FSR	RCLK+	RCOut1+	V_A	GND	V_E	GND_E	DQd0+	V_DR	DQd3+	GND_DR	DQd6+	V_DR	DQd9+	GND_DR	DQd11+	DQd11-	GND_DR	Υ

<sup>10 11 12 13</sup> 14 15 16 17 The center ground pins are for thermal dissipation and must be soldered to a ground plane to ensure rated performance. See Section 4.4 for more information.

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# 3.1 Pin Attributes

Table 3-1. Pin Attributes — Analog Front-End and Clock Balls

PIN NO.	NAME	PIN Attributes — Analog Front-En	DESCRIPTION
H1 J1 N1 M1	VinI+ VinI- VinQ+ VinQ-	AGND VCMO Control from VCMO AGND AGND AGND	Differential signal I- and Q-inputs. In the Non-Dual Edge Sampling (Non-DES) Mode, each I- and Q-input is sampled and converted by its respective channel with each positive transition of the CLK input. In Non-ECM (Non-Extended Control Mode) and DES Mode, both channels sample the I-input. In Extended Control Mode (ECM), the Q-input may optionally be selected for conversion in DES Mode by the DEQ Bit (Addr: 0h, Bit 6).  Each I- and Q-channel input has an internal common mode bias that is disabled when DC-coupled Mode is selected. Both inputs must be either AC- or DC-coupled. The coupling mode is selected by the V <sub>CMO</sub> Pin.  In Non-ECM, the full-scale range of these inputs is determined by the FSR Pin; both I- and Q-channels have the same full-scale input range. In ECM, the full-scale input range of the I- and Q-channel inputs may be independently set via the Control Register (Addr: 3h and Addr: Bh).  The input offset may also be adjusted in ECM.
U2 V1	CLK+ CLK-	AGND 50k VBIAS	Differential Converter Sampling Clock. In the Non-DES Mode, the analog inputs are sampled on the positive transitions of this clock signal. In the DES Mode, the selected input is sampled on both transitions of this clock. This clock must be AC-coupled.
V2 W1	DCLK_RST+ DCLK_RST-	VA AGND  VA  AGND  AGND	Differential DCLK Reset. A positive pulse on this input is used to reset the DCLKI and DCLKQ outputs of two or more ADC12D1800s in order to synchronize them with other ADC12D1800s in the system. DCLKI and DCLKQ are always in phase with each other, unless one channel is powered down, and do not require a pulse from DCLK_RST to become synchronized. The pulse applied here must meet timing relationships with respect to the CLK input. Although supported, this feature has been superseded by AutoSync.



Table 3-1. Pin Attributes — Analog Front-End and Clock Balls (continued)

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
C2	V <sub>смо</sub>	V <sub>CMO</sub> V <sub>CMO</sub> V <sub>CMO</sub> V <sub>CMO</sub> Enable AC Coupling	Common Mode Voltage Output or Signal Coupling Select. If AC-coupled operation at the analog inputs is desired, this pin should be held at logic-low level. This pin is capable of sourcing/ sinking up to 100 µA. For DC-coupled operation, this pin should be left floating or terminated into high-impedance. In DC-coupled Mode, this pin provides an output voltage which is the optimal common-mode voltage for the input signal and should be used to set the common-mode voltage of the driving buffer.
B1	$V_{BG}$	VA GND	Bandgap Voltage Output or LVDS Common-mode Voltage Select. This pin provides a buffered version of the bandgap output voltage and is capable of sourcing/sinking 100 uA and driving a load of up to 80 pF. Alternately, this pin may be used to select the LVDS digital output common-mode voltage. If tied to logic-high, the 1.2V LVDS common-mode voltage is selected; 0.8V is the default.
C3 D3	Rext+ Rext-	VA GND	External Reference Resistor terminals. A 3.3 k $\Omega$ ±0.1% resistor should be connected between Rext+/ The Rext resistor is used as a reference to trim internal circuits which affect the linearity of the converter; the value and precision of this resistor should not be compromised.
C1 D2	Rtrim+ Rtrim-	V <sub>A</sub> V <sub>A</sub> O  O  O  O  O  O  O  O  O  O  O  O  O	Input Termination Trim Resistor terminals. A 3.3 k $\Omega$ ±0.1% resistor should be connected between Rtrim+/ The Rtrim resistor is used to establish the calibrated 100 $\Omega$ input impedance of Vinl, VinQ and CLK. These impedances may be fine tuned by varying the value of the resistor by a corresponding percentage; however, the tuning range and performance is not ensured for such an alternate value.
E2 F3	Tdiode+ Tdiode-	Tdiode_P GND	Temperature Sensor Diode Positive (Anode) and Negative (Cathode) Terminals. This set of pins is used for die temperature measurements. It has not been fully characterized.



Table 3-1. Pin Attributes — Analog Front-End and Clock Balls (continued)

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
Y4 W5	RCLK+ RCLK-	AGND 50k VBIAS AGND	Reference Clock Input. When the AutoSync feature is active, and the ADC12D1800 is in Slave Mode, the internal divided clocks are synchronized with respect to this input clock. The delay on this clock may be adjusted when synchronizing multiple ADCs. This feature is available in ECM via Control Register (Addr: Eh).
Y5 U6 V6 V7	RCOut1+ RCOut1- RCOut2+ RCOut2-	100Ω	Reference Clock Output 1 and 2. These signals provide a reference clock at a rate of CLK/4, when enabled, independently of whether the ADC is in Master or Slave Mode. They are used to drive the RCLK of another ADC12D1800, to enable automatic synchronization for multiple ADCs (AutoSync feature). The impedance of each trace from RCOut1 and RCOut2 to the RCLK of another ADC12D1800 should be $100\Omega$ differential. Having two clock outputs allows the auto-synchronization to propagate as a binary tree. Use the DOC Bit (Addr: Eh, Bit 1) to enable/ disable this feature; default is disabled.

Table 3-2. Pin Attributes — Control and Status Balls

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
V5	DES	V <sub>A</sub> GND	Dual Edge Sampling (DES) Mode select. In the Non-Extended Control Mode (Non-ECM), when this input is set to logic-high, the DES Mode of operation is selected, meaning that the VinI input is sampled by both channels in a time-interleaved manner. The VinQ input is ignored. When this input is set to logic-low, the device is in Non-DES Mode, i.e. the I- and Q-channels operate independently. In the Extended Control Mode (ECM), this input is ignored and DES Mode selection is controlled through the Control Register by the DES Bit (Addr: 0h, Bit 7); default is Non-DES Mode operation.
V4	CalDly	V <sub>A</sub> GND	Calibration Delay select. By setting this input logichigh or logic-low, the user can select the device to wait a longer or shorter amount of time, respectively, before the automatic power-on self-calibration is initiated. This feature is pin-controlled only and is always active during ECM and Non-ECM.



Table 3-2. Pin Attributes — Control and Status Balls (continued)

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
D6	CAL	VA GND	Calibration cycle initiate. The user can command the device to execute a self-calibration cycle by holding this input high a minimum of t <sub>CAL_H</sub> after having held it low a minimum of t <sub>CAL_L</sub> . If this input is held high at the time of power-on, the automatic power-on calibration cycle is inhibited until this input is cycled low-then-high. This pin is active in both ECM and Non-ECM. In ECM, this pin is logically OR'd with the CAL Bit (Addr: 0h, Bit 15) in the Control Register. Therefore, both pin and bit must be set low and then either can be set high to execute an on-command calibration.
B5	CalRun	VA GND	Calibration Running indication. This output is logic-high while the calibration sequence is executing. This output is logic-low otherwise.
U3 V3	PDI PDQ	V <sub>A</sub> 50 kΩ GND	Power Down I- and Q-channel. Setting either input to logic-high powers down the respective I- or Q-channel. Setting either input to logic-low brings the respective I- or Q-channel to an operational state after a finite time delay. This pin is active in both ECM and Non-ECM. In ECM, each Pin is logically OR'd with its respective Bit. Therefore, either this pin or the PDI and PDQ Bit in the Control Register can be used to power-down the I- and Q-channel (Addr: 0h, Bit 11 and Bit 10), respectively.
A4	TPM	V <sub>A</sub> GND	Test Pattern Mode select. With this input at logichigh, the device continuously outputs a fixed, repetitive test pattern at the digital outputs. In the ECM, this input is ignored and the Test Pattern Mode can only be activated through the Control Register by the TPM Bit (Addr: 0h, Bit 12).
A5	NDM	V <sub>A</sub> GND	Non-Demuxed Mode select. Setting this input to logic-high causes the digital output bus to be in the 1:1 Non-Demuxed Mode. Setting this input to logic-low causes the digital output bus to be in the 1:2 Demuxed Mode. This feature is pin-controlled only and remains active during ECM and Non-ECM.



Table 3-2. Pin Attributes — Control and Status Balls (continued)

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
Y3	FSR	VA GND	Full-Scale input Range select. In Non-ECM, this input must be set to logic-high; the full-scale differential input range for both I- and Q-channel inputs is set by this pin. In the ECM, this input is ignored and the full-scale range of the I- and Q-channel inputs is independently determined by the setting of Addr: 3h and Addr: Bh, respectively. Note that the logic-high FSR value in Non-ECM corresponds to the minimum allowed selection in ECM.
W4	DDRPh	VA GND	DDR Phase select. This input, when logic-low, selects the 0° Data-to-DCLK phase relationship. When logic-high, it selects the 90° Data-to-DCLK phase relationship, i.e. the DCLK transition indicates the middle of the valid data outputs. This pin only has an effect when the chip is in 1:2 Demuxed Mode, i.e. the NDM pin is set to logic-low. In ECM, this input is ignored and the DDR phase is selected through the Control Register by the DPS Bit (Addr: 0h, Bit 14); the default is 0° Mode.
В3	ECE	VA 50 kΩ GND	Extended Control Enable bar. Extended feature control through the SPI interface is enabled when this signal is asserted (logic-low). In this case, most of the direct control pins have no effect. When this signal is de-asserted (logic-high), the SPI interface is disabled, all SPI registers are reset to their default values, and all available settings are controlled via the control pins.
C4	SCS	VA 100 KΩ GND	Serial Chip Select bar. In ECM, when this signal is asserted (logic-low), SCLK is used to clock in serial data which is present on SDI and to source serial data on SDO. When this signal is deasserted (logic-high), SDI is ignored and SDO is in TRI-STATE.
C5	SCLK	VA 1000 KΩ GND	Serial Clock. In ECM, serial data is shifted into and out of the device synchronously to this clock signal. This clock may be disabled and held logic-low, as long as timing specifications are not violated when the clock is enabled or disabled.



Table 3-2. Pin Attributes — Control and Status Balls (continued)

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
B4	SDI	V <sub>A</sub> 100 kΩ GND	Serial Data-In. In ECM, serial data is shifted into the device on this pin while SCS signal is asserted (logic-low).
АЗ	SDO	V <sub>A</sub> GND	Serial Data-Out. In ECM, serial data is shifted out of the device on this pin while SCS signal is asserted (logic-low). This output is at TRI-STATE when SCS is de-asserted.
D1, D7, E3, F4, W3, U7	DNC	NONE	Do Not Connect. These pins are used for internal purposes and should not be connected, i.e. left floating. Do not ground.
C7	NC	NONE	Not Connected. This pin is not bonded and may be left floating or connected to any potential.

Table 3-3. Pin Attributes — Power and Ground Balls

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
A2, A6, B6, C6, D8, D9, E1, F1, H4, N4, R1, T1, U8, U9, W6, Y2, Y6	$V_{A}$	NONE	Power Supply for the Analog circuitry. This supply is tied to the ESD ring. Therefore, it must be powered up before or with any other supply.
G1, G3, G4, H2, J3, K3, L3, M3, N2, P1, P3, P4, R3, R4	$V_{TC}$	NONE	Power Supply for the Track-and-Hold and Clock circuitry.
A11, A15, C18, D11, D15, D17, J17, J20, R17, R20, T17, U11, U15, U16, Y11, Y15	$V_{DR}$	NONE	Power Supply for the Output Drivers.
A8, B9, C8, V8, W9, Y8	$V_{E}$	NONE	Power Supply for the Digital Encoder.
J4, K2	VbiasI	NONE	Bias Voltage I-channel. This is an externally decoupled bias voltage for the I-channel. Each pin should individually be decoupled with a 100 nF capacitor via a low resistance, low inductance path to GND.
L2, M4	VbiasQ	NONE	Bias Voltage Q-channel. This is an externally decoupled bias voltage for the Q-channel. Each pin should individually be decoupled with a 100 nF capacitor via a low resistance, low inductance path to GND.



Table 3-3. Pin Attributes — Power and Ground Balls (continued)

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION	
A1, A7, B2, B7, D4, D5, E4, K1, L1, T4, U4, U5, W2, W7, Y1, Y7, H8:N13	GND	NONE	Ground Return for the Analog circuitry.	
F2, G2, H3, J2, K4, L4, M2, N3, P2, R2, T2, T3, U1	GND <sub>TC</sub>	NONE	Ground Return for the Track-and-Hold and Cloc circuitry.	
A13, A17, A20, D13, D16, E17, F17, F20, M17, M20, U13, U17, V18, Y13, Y17, Y20	GND <sub>DR</sub>	NONE	Ground Return for the Output Drivers.	
A9, B8, C9, V9, W8, Y9	GND <sub>E</sub>	NONE	Ground Return for the Digital Encoder.	

Table 3-4. Pin Attributes — High-Speed Digital Outputs

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
K19 K20 L19 L20	DCLKI+ DCLKI- DCLKQ+ DCLKQ-	- Je de la constant d	Data Clock Output for the I- and Q-channel data bus. These differential clock outputs are used to latch the output data and, if used, should always be terminated with a 100Ω differential resistor placed as closely as possible to the differential receiver. Delayed and non-delayed data outputs are supplied synchronously to this signal. In 1:2 Demux Mode or Non-Demux Mode, this signal is at ¼ or ½ the sampling clock rate, respectively. DCLKI and DCLKQ are always in phase with each other, unless one channel is powered down, and do not require a pulse from DCLK_RST to become synchronized.
K17 K18 L17 L18	ORI+ ORI- ORQ+ ORQ-	- January DR GND	Out-of-Range Output for the I- and Q-channel. This differential output is asserted logic-high while the over- or under-range condition exists, i.e. the differential signal at each respective analog input exceeds the full-scale value. Each OR result refers to the current Data, with which it is clocked out. If used, each of these outputs should always be terminated with a $100\Omega$ differential resistor placed as closely as possible to the differential receiver.



Table 3-4. Pin Attributes — High-Speed Digital Outputs (continued)

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
J18 J19 H19 H20 H17 H18 G19 G20 G17 G18 F18 F19 E20 D19 D20 D18 E18 C19 C20 B19 B20 B18 C17 . M18 M19 N20 N17 N18 P19 N20 N17 N18 P19 P20 P17 P18 R18 R19 T19 T20 U19 U20 U18 T18 V19 V20 W19 V20 W19 V20 W18 V17	DI11+ DI10- DI10- DI9+ DI9- DI8- DI8- DI7- DI6- DI5- DI5- DI4+ DI3- DI3- DI2- DI1- DI1- DI0- DI0- DI1- DI1- DI0- DI0- DI1- DI0- DI0- DI0- DI0- DI0- DI0- DI0- DI0	V <sub>DR</sub> + J <sub>DR</sub> GND	I- and Q-channel Digital Data Outputs. In Non-Demux Mode, this LVDS data is transmitted at the sampling clock rate. In Demux Mode, these outputs provide ½ the data at ½ the sampling clock rate, synchronized with the delayed data, i.e. the other ½ of the data which was sampled one clock cycle earlier. Compared with the Dld and DQd outputs, these outputs represent the later time samples. If used, each of these outputs should always be terminated with a 100Ω differential resistor placed as closely as possible to the differential receiver.



Table 3-4. Pin Attributes — High-Speed Digital Outputs (continued)

PIN NO.	NAME	EQUIVALENT CIRCUIT	DESCRIPTION
A18 A19 B17 C16 A16 B16 B15 C15 C14 D14 A14 B14 B13 C13 C12 D12 A12 B12 B11 C11 C10 D10 A10 B10 . Y18 Y19 W17 V16 Y16 W16 W15 V15 V14 U14 Y14 W14 W14 W13 V13 V12 U12 Y12 W11 V11 V10 U10 Y10 W10	DId11+ DId10- DId10- DId9+ DId9- DId8- DId8- DId7- DId6- DId6- DId5- DId5- DId4+ DId3- DId2- DId1- DId1- DId1- DId0	DR GND	Delayed I- and Q-channel Digital Data Outputs. In Non-Demux Mode, these outputs are at TRI-STATE. In Demux Mode, these outputs provide $\frac{1}{2}$ the data at $\frac{1}{2}$ the sampling clock rate, synchronized with the non-delayed data, i.e. the other $\frac{1}{2}$ of the data which was sampled one clock cycle later. Compared with the DI and DQ outputs, these outputs represent the earlier time samples. If used, each of these outputs should always be terminated with a $100\Omega$ differential resistor placed as closely as possible to the differential receiver.



# 4 Specifications

## 4.1 Absolute Maximum Ratings

(see (1)(2))

(see ····)			
	MIN	MAX	UNIT
Supply voltage (V <sub>A</sub> , V <sub>TC</sub> , V <sub>DR</sub> , V <sub>E</sub> )		2.2	V
Supply difference $\max(V_{A/TC/DR/E})$ - $\min(V_{A/TC/DR/E})$	0	100	mV
Voltage on any input pin (except V <sub>IN</sub> ±)	-0.15	(V <sub>A</sub> + 0.15)	V
V <sub>IN</sub> ± voltage range	-0.5	2.5	V
Ground difference max(GND <sub>TC/DR/E</sub> ) -min(GND <sub>TC/DR/E</sub> )	0	100	mV
Input current at any pin <sup>(3)</sup>	-50	50	mA
ADC12D1800 package power dissipation at T <sub>A</sub> ≤ 65°C <sup>(3)</sup>		4.95	W
Storage temperature, T <sub>stg</sub>	-65	150	°C

<sup>(1)</sup> Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. There is no specification of operation at the Absolute Maximum Ratings. Section 4.3 indicates conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

(2) All voltages are measured with respect to GND = GND<sub>TC</sub> = GND<sub>DR</sub> = GND<sub>E</sub> = 0V, unless otherwise specified.

# 4.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2500	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	V
		Machine model (MM)	±250	

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

<sup>(3)</sup> When the input voltage at any pin exceeds the power supply limits (for example, less than GND or greater than V<sub>A</sub>), the current at that pin should be limited to 50 mA. In addition, over-voltage at a pin must adhere to the maximum voltage limits. Simultaneous over-voltage at multiple pins requires adherence to the maximum package power dissipation limits. These dissipation limits are calculated using JEDEC JESD51-7 thermal model. Higher dissipation may be possible based on specific customer thermal situation and specified package thermal resistances from junction to case.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



#### 4.3 **Recommended Operating Conditions**

(see (1)(2))

		MIN	MAX	UNIT
Ambient temperature range	T <sub>A</sub> ADC12D1800 (Standard JEDEC thermal model)	-40	50	°C
	T <sub>A</sub> ADC12D1800 (Enhanced thermal model/heatsink)	-40	85	°C
T <sub>J</sub> Junction temperature range	(applies only to maximum operating speed)		120	°C
Supply voltage (V <sub>A</sub> , V <sub>TC</sub> , V <sub>E</sub> )		+1.8	+1.8 +2.0	
Driver supply voltage (V <sub>DR</sub> )		+1.8	$V_{A}$	V
V <sub>IN</sub> +/- Voltage range (3)		-0.4	2.4 (DC-coupled)	V
V <sub>IN</sub> +/- Differential voltage rang	e <sup>(4)</sup>	1.0 (DC-coupled at 100% duty cycle) 2.0 (DC-coupled at 20% duty cycle) 2.8 (DC-coupled at 10% duty cycle)		V
V <sub>IN</sub> +/- Current range <sup>(3)</sup>		-50	±50 peak (A.Ccoupled)	mA
V // Dower	(maintaining common mode voltage, A.Ccoupled)		15.3	
V <sub>IN</sub> +/- Power	(not maintaining common mode voltage, A.Ccoupled)		17.1	dBm
Ground difference max(GND <sub>TC/DR/E</sub> ) – min(GNI	O <sub>TC/DR/E</sub> )		0	V
CLK+/- Voltage range		0	$V_{A}$	V
Differential CLK amplitude V <sub>P</sub>	P	0.4	2	V
Common mode input voltage \	<b>/</b> смі	V <sub>CMO</sub> - 150	V <sub>CMO</sub> + 150	mV

Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. There is no specification of operation at the Absolute Maximum Ratings. Section 4.3 indicates conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions. All voltages are measured with respect to  $GND = GND_{TC} = GND_{DR} = GND_{E} = 0V$ , unless otherwise specified.

### **Thermal Information**

		ADC12D1800	
	THERMAL METRIC <sup>(1)</sup>	NXA (BGA)	UNIT
		292 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	16	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	2.9	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	2.5	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

Proper common mode voltage must be maintained to ensure proper output codes, especially during input overdrive.

This rating is intended for DC-coupled applications; the voltages listed may be safely applied to V<sub>IN</sub>+/- for the life-time duty-cycle of the

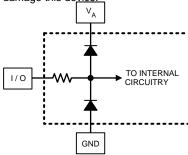


### 4.5 Converter Electrical Characteristics: Static Converter Characteristics

Unless otherwise specified, the following apply after calibration for  $V_A = V_{DR} = V_{TC} = V_E = +1.9V$ ; I- and Q-channels, AC-coupled, unused channel terminated to AC ground, FSR Pin = High;  $C_L = 10$  pF; Differential, AC coupled Sine Wave Sampling Clock,  $f_{CLK} = 1.8$  GHz at  $0.5 \ V_{P-P}$  with 50% duty cycle (as specified);  $V_{BG} = Floating$ ; Extended Control Mode with Register 6h written to 1C00h; Rext = Rtrim =  $3300\Omega \pm 0.1\%$ ; Analog Signal Source Impedance =  $100\Omega$  Differential; 1:2 Demultiplex Non-DES Mode; Duty Cycle Stabilizer on. Max limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C, unless otherwise noted. (1)

	PARAMETER	TEST CONDITIONS	TYP	MAX	UNIT
	Resolution with no missing codes	$T_A = T_{MIN}$ to $T_{MAX}$ , $T_J < 105$ °C		12	bits
INL	Integral non-linearity (Best fit)	1 MHz DC-coupled over-ranged sine wave	±2.5		LSB
DNL	Differential non-linearity	1 MHz DC-coupled over-ranged sine wave	±0.4		LSB
V <sub>OFF</sub>	Offset error		5		LSB
V <sub>OFF</sub> _ADJ	Input offset adjustment range	Extended Control Mode	±45		mV
PFSE	Positive full-scale error	See (4)		±25	mV
NFSE	Negative full-scale error	See (4)		±25	mV
	Out of range output and (5)	$(V_{IN}+)$ - $(V_{IN}-)$ > + full scale		4095	
	Out-of-range output code (5)	$(V_{IN}+) - (V_{IN}-) < -$ full scale		0	

(1) The analog inputs, labeled I/O, are protected as shown below. Input voltage magnitudes beyond the Absolute Maximum Ratings may damage this device.



- (2) To ensure accuracy, it is required that V<sub>A</sub>, V<sub>TC</sub>, V<sub>E</sub> and V<sub>DR</sub> be well-bypassed. Each supply pin must be decoupled with separate bypass capacitors.
- (3) Typical figures are at T<sub>A</sub> = 25°C, and represent most likely parametric norms. Test limits are specified to TI's AOQL (Average Outgoing Quality Level).
- (4) Calculation of Full-Scale Error for this device assumes that the actual reference voltage is exactly its nominal value. Full-Scale Error for this device, therefore, is a combination of Full-Scale Error and Reference Voltage Error. See Figure 4-1. For relationship between Gain Error and Full-Scale Error, see Specification Definitions for Gain Error.
- (5) This parameter is ensured by design and is not tested in production.



### 4.6 Converter Electrical Characteristics: Dynamic Converter Characteristics

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_A < 105$ °C

	PARAMETER	TEST CO	ONDITIONS	MIN	TYP	MAX	UNIT
		Non-DES Mode			2.8		GHz
FPBW	Full power bandwidth	DESI, DESQ Mode			1.25		GHz
		DESIQ Mode			1.75		GHz
		Non-DES Mode	D.C. to Fs/2		0.5		dB
			D.C. to Fs		1.2		dB
	Gain flatness	DESI, DESQ Mode	D.C. to Fs/2		4.0		dB
		DESIQ Mode	D.C. to Fs/2		3.6		dB
CER	Code error rate		'		10 <sup>-18</sup>		Error/S ample
NPR	Noise power ratio	See (1)			48.5		dB
	3rd order intermodulation	DESIQ Mode			-61		dBFS
IMD3	distortion	FIN1 = 1212.52MHz at FIN2 = 1217.52 MHz at			-54		dBc
		50Ω single-ended termin	nation, DES Mode		-153.5		dBm/Hz
					-152.5		dBFS/H
	Noise floor density	Wideband input, DES Mode (2)			-152.6		dBm/Hz
					-151.6		dBFS/H
NON-DE	S MODE <sup>(3)(4)</sup>	1		-			
		$A_{IN} = 125 \text{ MHz at -0.5 d}$	BFS		9.4		bits
		$A_{IN} = 248 \text{ MHz at -0.5 d}$	BFS	8.4	9.2		bits
ENOB	Effective Number of Bits	$A_{IN} = 498 \text{ MHz at -0.5 d}$	BFS	8.4	9.1		bits
		$A_{IN} = 1147 \text{ MHz at -0.5}$	dBFS		8.5		bits
		A <sub>IN</sub> = 1448 MHz at -0.5	dBFS		8.4		bits
		A <sub>IN</sub> = 125 MHz at -0.5 d	BFS		58		dB
		$A_{IN} = 248 \text{ MHz at -0.5 d}$	BFS	52.1	57.3		dB
SINAD	Signal-to-Noise Plus Distortion Ratio	$A_{IN} = 498 \text{ MHz at -0.5 d}$	BFS	52.1	56.3		dB
	Distortion read	A <sub>IN</sub> = 1147 MHz at -0.5	dBFS		52.9		dB
		$A_{IN} = 1448 \text{ MHz at -0.5}$	dBFS		52.5		dB
		A <sub>IN</sub> = 125 MHz at -0.5 d	BFS		58.6		dB
		$A_{IN} = 248 \text{ MHz at -0.5 d}$	BFS	52.9	57.8		dB
SNR	Signal-to-Noise Ratio	$A_{IN} = 498 \text{ MHz at -0.5 d}$	BFS	52.9	57.3		dB
		$A_{IN} = 1147 \text{ MHz at -0.5}$	dBFS		53.9		dB
		A <sub>IN</sub> = 1448 MHz at -0.5	dBFS		53.1		dB
		$A_{IN} = 125 \text{ MHz at } -0.5 \text{ d}$	BFS		-68.5		dB
		$A_{IN} = 248 \text{ MHz at -0.5 d}$	BFS	-60	-66.6		dB
THD	Total Harmonic Distortion	$A_{IN} = 498 \text{ MHz at -0.5 d}$	BFS	-60	-63.2		dB
		$A_{IN} = 1147 \text{ MHz at -0.5}$	dBFS		-59.5		dB
		A <sub>IN</sub> = 1448 MHz at -0.5	dBFS		-61.1		dB

<sup>(1)</sup> The NPR was measured using an Agilent N6030A Arbitrary Waveform Generator (ARB) to generate the input signal. See the Wideband Performance for an example spectrum. The "noise" portion of the signal was created by tones spaced at 500 kHz and the "notch" was a 25 MHz absence of tones centered at 320 MHz. The bandwidth of this equipment is only 500 MHz, so the final reported NPR was extrapolated from the measured NPR as if the entire Nyquist band were occupied with noise.

(4) The Fs/2 spur was removed from all the dynamic performance specifications.

<sup>(2)</sup> The Noise Floor Density was measured for two conditions: the analog input terminated with 50Ω, and in the presence of a 500 MHz wideband noise signal with total power just below the maximum input level to the ADC. In both cases, the spurs at DC, Fs/4 and Fs/2 were not included in the noise floor calculation. The power over the entire Nyquist band (except for the noise signal) was integrated and the average number is reported.

<sup>(3)</sup> The Dynamic Specifications are ensured for room to hot ambient temperature only (25°C to 85°C). Refer to the plots of the dynamic performance vs. temperature in the Typical Performance Plots to see typical performance from cold to room temperature (-40°C to 25°C).



# Converter Electrical Characteristics: Dynamic Converter Characteristics (continued)

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_A < 105$ °C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		73		dBc
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		87		dBc
2nd Harm	Second Harmonic Distortion	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		70		dBc
Tiaiiii	Distortion	A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		62		dBc
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		66		dBc
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		76.8		dBc
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		67.4		dBc
3rd Harm	Third Harmonic Distortion	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		66.3		dBc
		A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		63		dBc
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		63.6		dBc
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		73		dBc
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		67.5	58	dBc
SFDR	Spurious-Free Dynamic Range	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		66.1	58	dBc
	range	A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		60.2		dBc
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		60.3		dBc
DES MOD	DE <sup>(3)(4) (5)</sup>					-
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		8.9		bits
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		8.8	8.4	bits
ENOB	Effective number of bits	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		8.6		bits
		A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		8		bits
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		8		bits
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		55.6		dB
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		54.8	52.1	dB
SINAD	Signal-to-noise plus distortion ratio	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		53.8		dB
	distortion ratio	A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		50		dB
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		49.8		dB
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		55.8		dB
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		55.3	52.9	dB
SNR	Signal-to-noise ratio	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		54.5		dB
		A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		50.4		dB
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		50.1		dB
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		-67.8		dB
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		-65	-60	dB
THD	Total harmonic distortion	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		-62		dB
		A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		-60.6		dB
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		-61.9		dB
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		78		dBc
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		74.4		dBc
2nd Harm	Second harmonic distortion	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		72.5		dBc
ı lalılı	distortion	A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		70.5		dBc
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		72.8		dBc

<sup>(5)</sup> These measurements were taken in Extended Control Mode (ECM) with the DES Timing Adjust feature enabled (Addr: 7h). This feature is used to reduce the interleaving timing spur amplitude, which occurs at fs/2-fin, and thereby increase the SFDR, SINAD and ENOB.



# Converter Electrical Characteristics: Dynamic Converter Characteristics (continued)

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		72.6		dBc
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		66.5		dBc
3rd Harm	Third harmonic distortion	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		63.2		dBc
		A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		61.8		dBc
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		63.8		dBc
		A <sub>IN</sub> = 125 MHz at -0.5 dBFS		58.9		dBc
		A <sub>IN</sub> = 248 MHz at -0.5 dBFS		60.4	58	dBc
SFDR	Spurious-free dynamic range	A <sub>IN</sub> = 498 MHz at -0.5 dBFS		60.5		dBc
	Tungo	A <sub>IN</sub> = 1147 MHz at -0.5 dBFS		56.7		dBc
		A <sub>IN</sub> = 1448 MHz at -0.5 dBFS		55.6		dBc

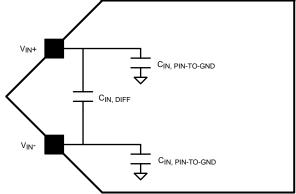
# 4.7 Converter Electrical Characteristics: Analog Input and Output and Reference Characteristics

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
ANALOG	INPUTS						
V <sub>IN_FSR</sub>	Analog differential input full scale range	Non-Extended Control Mode	FSR Pin High	740	800	860	mV <sub>P-P</sub>
		Extended Control Mode	FM(14:0) = 4000 <b>h</b> (default)		800		mV <sub>P-P</sub>
			FM(14:0) = 7FFF <b>h</b>		1000		$mV_{P-P}$
	Analog input capacitance,	Differential			0.02		pF
0	non-DES mode (1) (2)	Each input pin to ground			1.6		pF
C <sub>IN</sub>	Analog input capacitance,	Differential			0.08		pF
	Analog input capacitance, DES mode <sup>(1)</sup> <sup>(2)</sup>	Each input pin to ground			2.2		pF
R <sub>IN</sub>	Differential input resistance			91	100	109	Ω

(1) This parameter is ensured by design and is not tested in production.

(2) The differential and pin-to-ground input capacitances are lumped capacitance values from design; they are defined as shown below.



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# Converter Electrical Characteristics: Analog Input and Output and Reference Characteristics *(continued)*

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
COMMON	MODE OUTPUT					
V <sub>CMO</sub>	Common mode output voltage	$I_{CMO} = \pm 100 \ \mu A$	1.15	1.25	1.35	V
TC_V <sub>CM</sub>	Common mode output voltage temperature coefficient	I <sub>CMO</sub> = ±100 μA		38		ppm/°C
V <sub>CMO_LVL</sub>	V <sub>CMO</sub> input threshold to set DC-coupling Mode			0.63		V
C <sub>L</sub> _V <sub>CMO</sub>	Maximum V <sub>CMO</sub> load capacitance	(1)			80	pF
BANDGA	P REFERENCE					
$V_{BG}$	Bandgap reference output voltage	I <sub>BG</sub> = ±100 μA	1.15	1.25	1.35	V
TC_V <sub>BG</sub>	Bandgap reference voltage temperature coefficient	I <sub>BG</sub> = ±100 μA		32		ppm/°C
C <sub>L</sub> _V <sub>BG</sub>	Maximum bandgap reference load capacitance	(1)			80	pF

# 4.8 Converter Electrical Characteristics: I-Channel to Q-Channel Characteristics

	PARAMETER	TEST CONDITIONS	TYP	LIM	UNIT
	Offset match		2		LSB
	Positive full-scale match	Zero offset selected in Control Register	2		LSB
	Negative full-scale match	Zero offset selected in Control Register	2		LSB
	Phase matching (I, Q)	f <sub>IN</sub> = 1.0 GHz	< 1		Degree
X-TALK	Crosstalk from I-channel (Aggressor) to Q-channel (Victim)	Aggressor = 867 MHz F.S. Victim = 100 MHz F.S.	-70		dB
	Crosstalk from Q-channel (Aggressor) to I-channel (Victim)	Aggressor = 867 MHz F.S. Victim = 100 MHz F.S.	-70		dB



# 4.9 Converter Electrical Characteristics: Sampling Clock Characteristics

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105^{\circ}C$ 

73 IVIII VIII VIII VIII VIII VIII VIII V							
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V <sub>IN_CLK</sub>	Differential sampling clock input	Sine wave clock Differential Peak-to-peak	0.4	0.6	2.0	V <sub>P-P</sub>	
	level <sup>(1)</sup>	Square wave clock Differential peak-to-peak	0.4	0.6	2.0	V <sub>P-P</sub>	
0	Sampling clock input capacitance	Differential		0.1		pF	
C <sub>IN_CLK</sub>	(2)	Each input to ground	1			pF	
R <sub>IN_CLK</sub>	Sampling clock differential input resistance			100		Ω	

<sup>(1)</sup> This parameter is ensured by design and/or characterization and is not tested in production.

# 4.10 Converter Electrical Characteristics: AutoSync Feature Characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>IN_RCLK</sub>	Differential RCLK input level	Differential peak-to-peak		360		$mV_{P-P}$
C	RCLK input capacitance	Differential		0.1		pF
C <sub>IN_RCLK</sub>		Each input to ground		1		pF
R <sub>IN_RCLK</sub>	RCLK differential input resistance			100		Ω
I <sub>IH_RCLK</sub>	Input leakage current; V <sub>IN</sub> = V <sub>A</sub>			22		μΑ
I <sub>IL_RCLK</sub>	Input leakage current; V <sub>IN</sub> = GND			-33		μΑ
V <sub>O_RCOUT</sub>	Differential RCOut Output Voltage			360		mV

# 4.11 Converter Electrical Characteristics: Digital Control and Output Pin Characteristics

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
DIGITAL CONTROL PINS (DES, CalDIy, CAL, PDI, PDQ, TPM, NDM, FSR, DDRPh, ECE, SCLK, SDI, SCS)								
V <sub>IH</sub>	Logic high input voltage		0.7.1/		0.2.3/	V		
$V_{IL}$	Logic low input voltage		0.7×V <sub>A</sub>		0.3 <b>×</b> V <sub>A</sub>	V		
I <sub>IH</sub>	Input leakage current; V <sub>IN</sub> = V <sub>A</sub>			0.02		μА		
	Input leakage current;	FSR, CalDly, CAL, NDM, TPM, DDRPh, DES		-0.02		μΑ		
I <sub>IL</sub>	V <sub>IN</sub> = GND	SCS, SCLK, SDI		-17		μА		
		PDI, PDQ, ECE		-38		μА		
C <sub>IN_DIG</sub>	Digital control pin input capacitance (1)	Measured from each control pin to GND		1.5		pF		

(1) This parameter is ensured by design and is not tested in production.

<sup>(2)</sup> This parameter is ensured by design and is not tested in production.



# Converter Electrical Characteristics: Digital Control and Output Pin Characteristics (continued)

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
DIGITAL O	JTPUT PINS (Data, DCLKI, DCLKQ,	ORI, ORQ)				•
		V <sub>BG</sub> = Floating, OVS = High	400	630	800	$mV_{P-P}$
	LVDC differential cutout valters	V <sub>BG</sub> = Floating, OVS = Low	230	460	630	$mV_{P-P}$
$V_{OD}$	LVDS differential output voltage	V <sub>BG</sub> = V <sub>A</sub> , OVS = High		670		mV <sub>P-P</sub>
		V <sub>BG</sub> = V <sub>A</sub> , OVS = Low		500		mV <sub>P-P</sub>
$\Delta V_{O\ DIFF}$	Change in LVDS output swing between logic levels			±1		mV
W	Outrot offers well-	V <sub>BG</sub> = Floating		0.8		V
V <sub>OS</sub>	Output offset voltage	$V_{BG} = V_A$		1.2		V
ΔV <sub>OS</sub>	Output offset voltage change between logic levels			±1		mV
I <sub>OS</sub>	Output short circuit current	V <sub>BG</sub> = Floating; D+ and D− connected to 0.8V		±4		mA
Z <sub>O</sub>	Differential output impedance			100		Ω
V <sub>OH</sub>	Logic high output level	CalRun, $I_{OH} = -100 \mu A$ , (2) SDO, $I_{OH} = -400 \mu A$ (2)		1.65		V
V <sub>OL</sub>	Logic low output level	CalRun, $I_{OL} = 100 \mu A$ , (2) SDO, $I_{OL} = 400 \mu A$ (2)		0.15		V
DIFFERENT	TIAL DCLK RESET PINS (DCLK_RS	iT)				
V <sub>CMI_DRST</sub>	DCLK_RST common mode input voltage			1.25		V
V <sub>ID_DRST</sub>	Differential DCLK_RST input voltage			V <sub>IN_CLK</sub>		V <sub>P-P</sub>
R <sub>IN_DRST</sub>	Differential DCLK_RST input resistance	(1)		100		Ω

<sup>(2)</sup> This parameter is ensured by design and/or characterization and is not tested in production.

# 4.12 Converter Electrical Characteristics: Power Supply Characteristics

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

	PARAMETER	TEST CONDITIONS	TYP	MAX	UNIT
		PDI = PDQ = Low	1345		mA
	Analan ayankı ayanant	PDI = Low; PDQ = High	730		mA
IA	Analog supply current	PDI = High; PDQ = Low	730		mA
		PDI = PDQ = High	15		mA
I <sub>TC</sub>		PDI = PDQ = Low	495		mA
	Track-and-hold and clock	PDI = Low; PDQ = High	295		mA
	supply current	PDI = High; PDQ = Low	295		mA
		PDI = PDQ = High	4		mA
		PDI = PDQ = Low	330		mA
	Output deiven averale averant	PDI = Low; PDQ = High	175		mA
I <sub>DR</sub>	Output driver supply current	PDI = High; PDQ = Low	175		mA
		PDI = PDQ = High	3		mA
		PDI = PDQ = Low	165		mA
l <sub>E</sub>	Digital encoder supply	PDI = Low; PDQ = High	85		mA
	current	PDI = High; PDQ = Low	85		mA
		PDI = PDQ = High	1		mA



# **Converter Electrical Characteristics: Power Supply Characteristics (continued)**

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

	PARAMETER	TEST (	TEST CONDITIONS		MAX	UNIT
	Total augusts august	1:2 Demux Mode PDI = PDQ = Low		2335	2481	mA
TOTAL	Total supply current	Non-Demux Mode PDI = PDQ = Low				mA
		1:2 Demux Mode	PDI = PDQ = Low	4.44	4.7	W
			PDI = Low; PDQ = High	2.44		W
P <sub>C</sub>	Power consumption		PDI = High; PDQ = Low	2.44		W
			PDI = PDQ = High	43.7		mW
		Non-Demux Mode	PDI = PDQ = Low	4.18		W

# 4.13 Converter Electrical Characteristics: AC Electrical Characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SAMPLIN	G CLOCK (CLK)	,	1			
f <sub>CLK (max)</sub>	Maximum sampling clock frequency				1.8	GHz
		Non-DES Mode; LFS = 0 <b>b</b>			300	MHz
f <sub>CLK (min)</sub>	Minimum sampling clock frequency	Non-DES Mode; LFS = 1 <b>b</b>			150	MHz
		DES Mode			500	MHz
	Sampling clock duty cycle	$f_{CLK(min)} \le f_{CLK} \le f_{CLK(max)}^{(1)}$	20%	50%	80%	
t <sub>CL</sub>	Sampling clock low time	See (2)	111	278		ps
t <sub>CH</sub>	Sampling clock high time	See (2)	111	278		ps
DATA CL	OCK (DCLKI, DCLKQ)	•	•			•
	DCLK duty cycle	See (2)	45%	50%	55%	
t <sub>SR</sub>	Setup time DCLK_RST±	See (1)		45		ps
t <sub>HR</sub>	Hold time DCLK_RST±	See (1)		45		ps
t <sub>PWR</sub>	Pulse width DCLK_RST±	See <sup>(2)</sup>	5			Sampling clock cycles
		90° Mode <sup>(2)</sup>			4	Sampling
tsync_dly	DCLK synchronization delay	0° Mode <sup>(2)</sup>			5	clock cycles
t <sub>LHT</sub>	Differential low-to-high transition time	10%-to-90%, C <sub>L</sub> = 2.5 pF		200		ps
t <sub>HLT</sub>	Differential high-to-low transition time	10%-to-90%, C <sub>L</sub> = 2.5 pF		200		ps
t <sub>SU</sub>	Data-to-DCLK setup time	90° Mode <sup>(2)</sup>		430		ps
t <sub>H</sub>	DCLK-to-data hold time	90° Mode <sup>(2)</sup>		430		ps
t <sub>OSK</sub>	DCLK-to-data output skew	50% of DCLK transition to 50% of Data transition (2)		±50		ps

<sup>(1)</sup> This parameter is ensured by design and/or characterization and is not tested in production.

This parameter is ensured by design and is not tested in production.

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# Converter Electrical Characteristics: AC Electrical Characteristics (continued)

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
DATA	INPUT-TO-OUTPUT					*
t <sub>AD</sub>	Aperture delay	Sampling CLK+ rise to acquisition of data		1.15		ns
$t_{AJ}$	Aperture jitter			0.2		ps (rms)
t <sub>OD</sub>	Sampling clock-to data output delay (in addition to latency)	50% of sampling clock transition to 50% of data transition		3.2		ns
	Latency in 1:2 Demux non-DES	DI, DQ outputs			34	
	mode <sup>(2)</sup>	Dld, DQd outputs			35	
		DI outputs			34	
	Latency in 1:4 Demux DES mode <sup>(2)</sup>	DQ outputs			34.5	
		Dld outputs			35	Sampling clock cycles
t <sub>LAT</sub>		DQd outputs			35.5	
	Latency in non-Demux non-DES	DI outputs			34	
	mode <sup>(2)</sup>	DQ outputs			34	
	Laterania and Damin DEC made (2)	DI outputs			34	
	Latency in non-Demux DES mode <sup>(2)</sup>	DQ Outputs			34.5	
t <sub>ORR</sub>	Over range recovery time	Differential V <sub>IN</sub> step from ±1.2V to 0V to accurate conversion		1		Sampling clock cycle
	Wake-up time (PDI/PDQ low to	Non-DES Mode <sup>(2)</sup>		500		ns
t <sub>WU</sub>	rated accuracy conversion)	DES Mode <sup>(2)</sup>		1		μs

# 4.14 Converter Timing Requirements: Serial Port Interface

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

		MIN	NOM	MAX	UNIT
f <sub>SCLK</sub>	Serial clock frequency (1)		15		MHz
	Serial clock low time	30			ns
	Serial clock high time	30			ns
t <sub>SSU</sub>	Serial data-to-serial clock rising setup time (1)		2.5		ns
t <sub>SH</sub>	Serial data-to-serial clock rising hold time (1)		1		ns
t <sub>SCS</sub>	SCS-to-serial clock rising setup time		2.5		ns
t <sub>HCS</sub>	SCS-to-serial clock falling hold time		1.5		ns
t <sub>BSU</sub>	Bus turn-around time		10		ns

<sup>(1)</sup> This parameter is ensured by design and is not tested in production.



# 4.15 Converter Switching Characteristics: Calibration

Limits are  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $T_J < 105$ °C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>CAL</sub>	Calibration cycle time	Non-ECM				Sampling
		ECM CSS = 0 <b>b</b>	5.2·10 <sup>7</sup>			clock
		ECM CSS = 1 <b>b</b>				
t <sub>CAL_L</sub>	CAL pin low time	See <sup>(1)</sup>	1280			Sampling
t <sub>CAL_H</sub>	CAL pin high time	See (1)	1280			clock cycles
t <sub>CalDly</sub>	Calibration delay determined by CalDly pin <sup>(1)</sup>	CalDly = low			2 <sup>24</sup>	Sampling
		CalDly = high			2 <sup>30</sup>	clock cycles

(1) This parameter is ensured by design and is not tested in production.

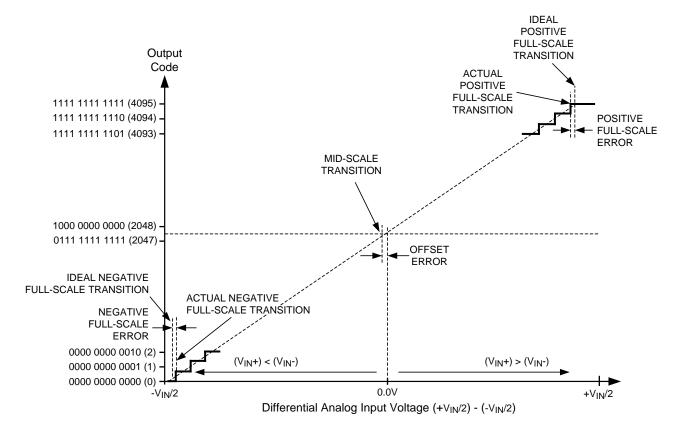
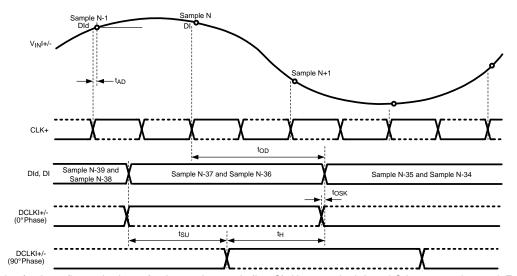


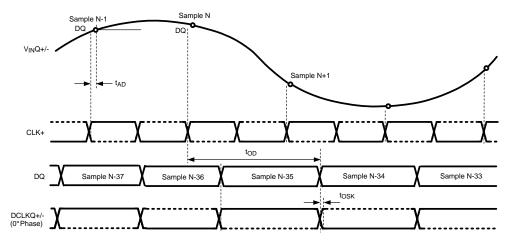
Figure 4-1. Input / Output Transfer Characteristic





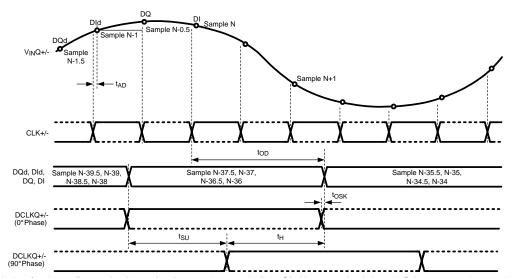
The timing for these figures is shown for the one input only (I or Q). However, both I- and Q-inputs may be used. For this case, the I-channel functions precisely the same as the Q-channel, with VinI, DCLKI, DId and DI instead of VinQ, DCLKQ, DQd and DQ. Both I- and Q-channel use the same CLK.

Figure 4-2. Clocking in 1:2 Demux Non-DES Mode



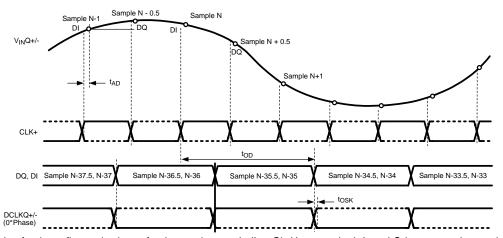
The timing for these figures is shown for the one input only (I or Q). However, both I- and Q-inputs may be used. For this case, the I-channel functions precisely the same as the Q-channel, with VinI, DCLKI, DId and DI instead of VinQ, DCLKQ, DQd and DQ. Both I- and Q-channel use the same CLK.

Figure 4-3. Clocking in Non-Demux Non-DES Mode



The timing for these figures is shown for the one input only (I or Q). However, both I- and Q-inputs may be used. For this case, the I-channel functions precisely the same as the Q-channel, with VinI, DCLKI, DId and DI instead of VinQ, DCLKQ, DQd and DQ. Both I- and Q-channel use the same CLK.

Figure 4-4. Clocking in 1:4 Demux DES Mode



The timing for these figures is shown for the one input only (I or Q). However, both I- and Q-inputs may be used. For this case, the I-channel functions precisely the same as the Q-channel, with VinI, DCLKI, DId and DI instead of VinQ, DCLKQ, DQd and DQ. Both I- and Q-channel use the same CLK.

Figure 4-5. Clocking in Non-Demux Mode DES Mode

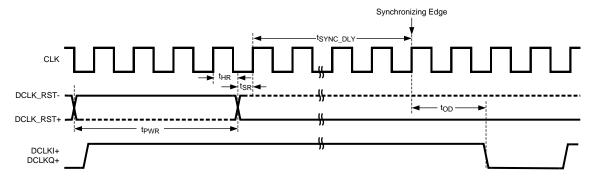


Figure 4-6. Data Clock Reset Timing (Demux Mode)



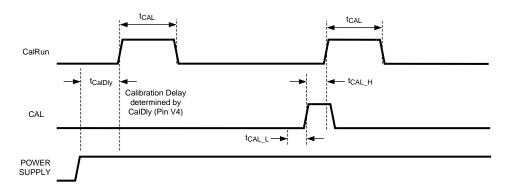


Figure 4-7. Power-on and On-Command Calibration Timing

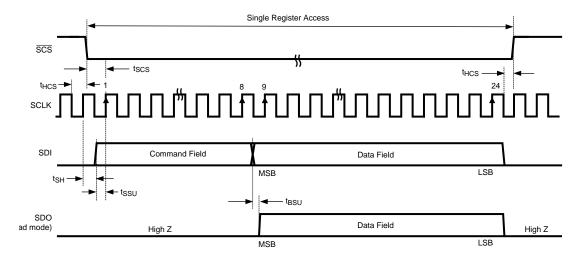
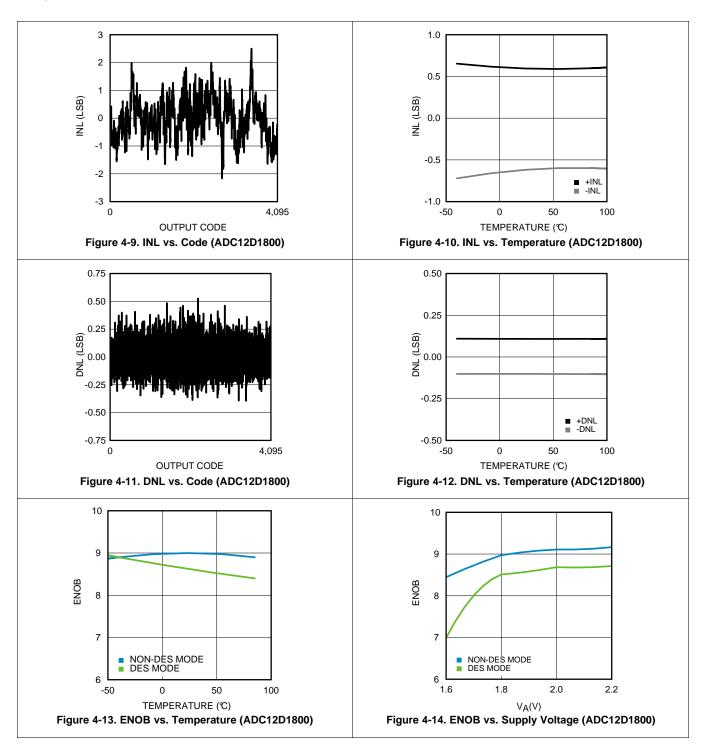


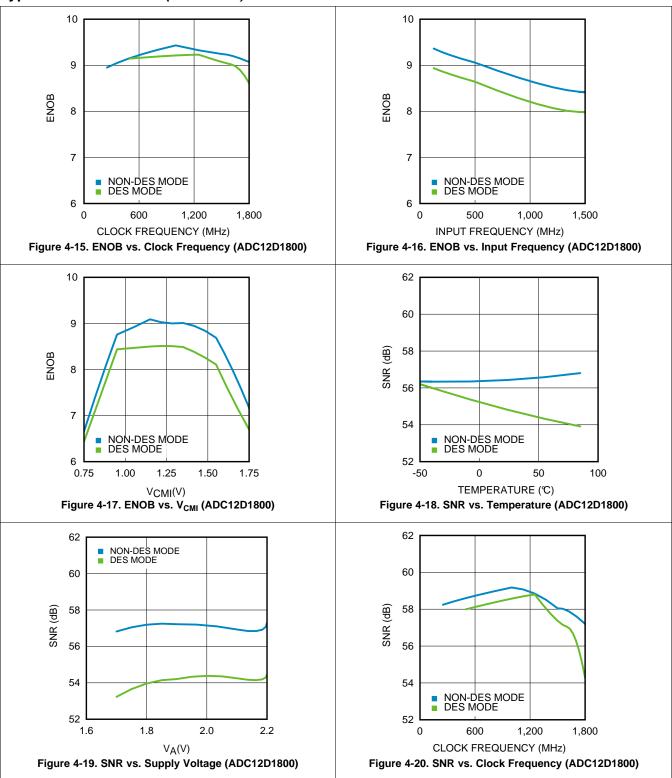
Figure 4-8. Serial Interface Timing

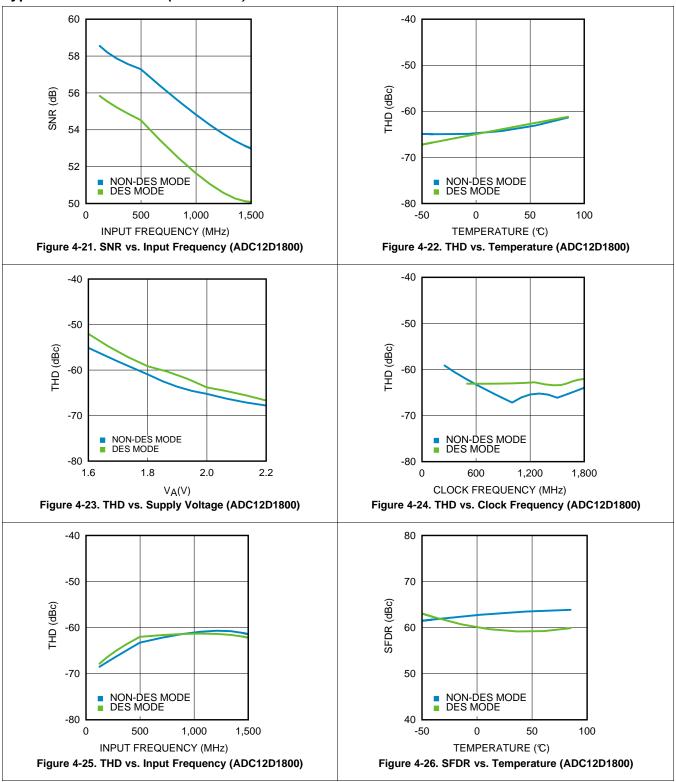
# 4.16 Typical Characteristics

 $V_A = V_{DR} = V_{TC} = V_E = 1.9V$ ,  $f_{CLK} = 1.8$  GHz,  $f_{IN} = 498$  MHz,  $T_A = 25$ °C, I-channel, 1:2 Demux Non-DES Mode (1:1 Demux Non-DES Mode has similar performance), unless otherwise stated. For NPR plots, notch width = 25 MHz, fc = 320 MHz.

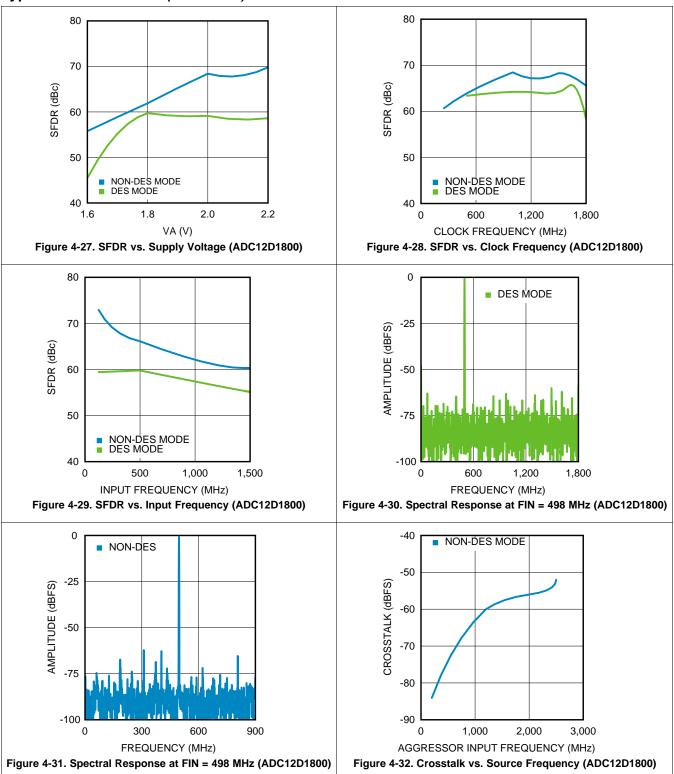












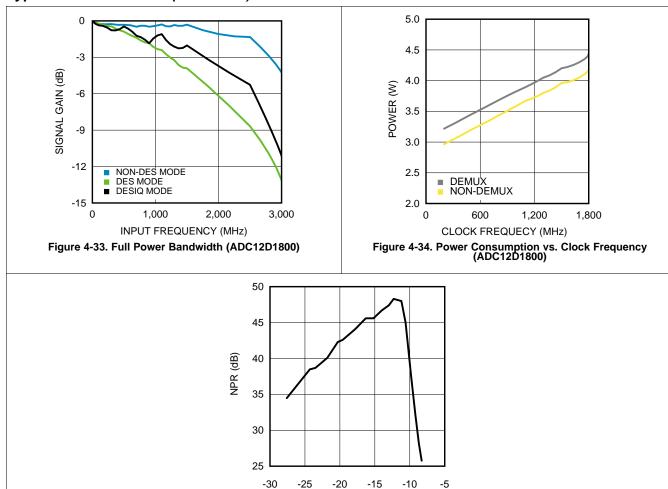


Figure 4-35. NPR vs. RMS Noise Loading Level (ADC12D1800)

RMS NOISE LOADING LEVEL (dB)



## **Detailed Description**

**ISTRUMENTS** 

#### Overview 5.1

The ADC12D1800 is a versatile A/D converter with an innovative architecture which permits very high speed operation. The controls available ease the application of the device to circuit solutions. Optimum performance requires adherence to the provisions discussed here and in the Section 6.1 Section. This section covers an overview, a description of control modes (Extended Control Mode and Non-Extended Control Mode), and features.

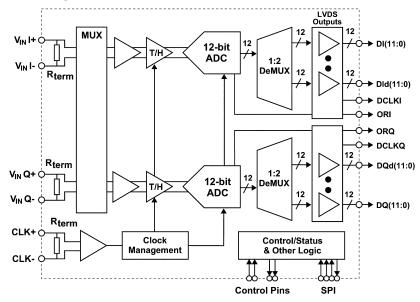
The ADC12D1800 uses a calibrated folding and interpolating architecture that achieves a high Effective Number of Bits (ENOB). The use of folding amplifiers greatly reduces the number of comparators and power consumption. Interpolation reduces the number of front-end amplifiers required, minimizing the load on the input signal and further reducing power requirements. In addition to correcting other non-idealities, on-chip calibration reduces the INL bow often seen with folding architectures. The result is an extremely fast, high performance, low power converter.

The analog input signal (which is within the converter's input voltage range) is digitized to twelve bits at speeds of 150 MSPS to 3.6 GSPS, typical. Differential input voltages below negative full-scale will cause the output word to consist of all zeroes. Differential input voltages above positive full-scale will cause the output word to consist of all ones. Either of these conditions at the I- or Q-input will cause the Out-of-Range I-channel or Q-channel output (ORI or ORQ), respectively, to output a logic-high signal.

In ECM, an expanded feature set is available via the Serial Interface. The ADC12D1800 builds upon previous architectures, introducing a new DES Mode Timing Adjust, AutoSync feature for multi-chip synchronization and increasing to 15-bit for gain and 12-bit plus sign for offset the independent programmable adjustment for each channel.

Each channel has a selectable output demultiplexer which feeds two LVDS buses. If the 1:2 Demux Mode is selected, the output data rate is reduced to half the input sample rate on each bus. When Non-Demux Mode is selected, the output data rate on each channel is at the same rate as the input sample clock and only one 12-bit bus per channel is active.

#### 5.2 **Functional Block Diagram**



# 5.3 Feature Description

The ADC12D1800 offers many features to make the device convenient to use in a wide variety of applications. Table 5-1 is a summary of the features available, as well as details for the control mode chosen. "N/A" means "Not Applicable."

Table 5-1. Features and Modes

FEATURE	NON-ECM	CONTROL PIN ACTIVE IN ECM	ECM	DEFAULT ECM STATE				
Input Control and Adjust								
AC/DC-coupled Mode Selection	Selected via V <sub>CMO</sub> (Pin C2)	Yes	Not available	N/A				
Input Full-scale Range Adjust	Selected via FSR (Pin Y3)	No	Selected via the Config Reg (Addr: 3h and Bh)	Low FSR value				
Input Offset Adjust Setting	Not available	N/A	Selected via the Config Reg (Addr: 2h and Ah)	Offset = 0 mV				
DES/Non-DES Mode Selection	Selected via DES (Pin V5)	No	Selected via the DES Bit (Addr: 0h; Bit: 7)	Non-DES Mode				
DES Timing Adjust	Not available	N/A	Selected via the DES Timing Adjust Reg (Addr: 7h)	Mid skew offset				
Sampling Clock Phase Adjust <sup>(1)</sup>	Not available	N/A	Selected via the Config Reg (Addr: Ch and Dh)	t <sub>AD</sub> adjust disabled				
	Oı	tput Control and	Adjust					
DDR Clock Phase Selection	Selected via DDRPh (Pin W4)	No	Selected via the DPS Bit (Addr: 0h; Bit: 14)	0° Mode				
LVDS Differential Voltage Amplitude Selection	Higher amplitude only	N/A	Selected via the OVS Bit (Addr: 0h; Bit: 13)	Higher amplitude				
LVDS Common-Mode Voltage Amplitude Selection	Selected via V <sub>BG</sub> (Pin B1)	Yes	Not available	N/A				
Output Formatting Selection	Offset Binary only	N/A	Selected via the 2SC Bit (Addr: 0h; Bit: 4)	Offset Binary				
Test Pattern Mode at Output	Selected via TPM (Pin A4)	No	Selected via the TPM Bit (Addr: 0h; Bit: 12)	TPM disabled				
Demux/Non-Demux Mode Selection	Selected via NDM (Pin A5)	Yes	Not available	N/A				
AutoSync	Not available	N/A	Selected via the Config Reg (Addr: Eh)	Master Mode, RCOut1/2 disabled				
DCLK Reset	Not available	N/A	Selected via the Config Reg (Addr: Eh; Bit 0)	DCLK Reset disabled				
Time Stamp	Not available	N/A	Selected via the TSE Bit (Addr: 0h; Bit: 3)	Time Stamp disabled				
		Calibration						
On-command Calibration	Selected via CAL (Pin D6)	Yes	Selected via the CAL Bit (Addr: 0h; Bit: 15)	N/A (CAL = 0)				
Power-on Calibration Delay Selection	Selected via CalDly (Pin V4)	Yes	Not available	N/A				
Calibration Adjust	Not available	N/A	Selected via the Config Reg (Addr: 4h)	t <sub>CAL</sub>				
Read/Write Calibration Settings	Not available	N/A	Selected via the SSC Bit (Addr: 4h; Bit: 7)	R/W calibration values disabled				
Power-Down								
Power down I-channel	Selected via PDI (Pin U3)	Yes	Selected via the PDI Bit (Addr: 0h; Bit: 11)					
Power down Q-channel	Selected via PDQ (Pin V3)	Yes	Selected via the PDQ Bit (Addr: 0h; Bit: 10)	Q-channel operational				

<sup>(1)</sup> Sampling Clock Phase Adjust cannot be used in DES mode (DESI, DESQ, DESIQ or DESCLKIQ) at CLK frequencies above 1600 MHz.



# 5.3.1 Input Control and Adjust

There are several features and configurations for the input of the ADC12D1800 so that it may be used in many different applications. This section covers AC/DC-coupled Mode, input full-scale range adjust, input offset adjust, DES/Non-DES Mode, DES Timing Adjust, and sampling clock phase adjust.

# 5.3.1.1 AC/DC-coupled Mode

The analog inputs may be AC or DC-coupled. See Section 5.5.1.1.10 for information on how to select the desired mode and Section 6.1.1.7 and Section 6.1.1.6 for applications information.

# 5.3.1.2 Input Full-Scale Range Adjust

The input full-scale range for the ADC12D1800 may be adjusted in ECM. In Non-ECM, the control pin must be set to logic-high; see Section 5.5.1.1.9. In ECM, the input full-scale range may be adjusted with 15-bits of precision. See  $V_{\text{IN\_FSR}}$  in Section 4.7 for electrical specification details. Note that the full-scale input range setting in Non-ECM (logic-high only) corresponds to the lowest full-scale input range settings in ECM. It is necessary to execute an on-command calibration following a change of the input full-scale range. See Section 5.6.1 for information about the registers.

#### 5.3.1.3 Input Offset Adjust

The input offset adjust for the ADC12D1800 may be adjusted with 12-bits of precision plus sign via ECM. See Section 5.6.1 for information about the registers.

# 5.3.1.4 DES Timing Adjust

The performance of the ADC12D1800 in DES Mode depends on how well the two channels are interleaved, i.e. that the clock samples either channel with precisely a 50% duty-cycle, each channel has the same offset (nominally code 2047/2048), and each channel has the same full-scale range. The ADC12D1800 includes an automatic clock phase background adjustment in DES Mode to automatically and continuously adjust the clock phase of the I- and Q-channels. In addition to this, the residual fixed timing skew offset may be further manually adjusted, and further reduce timing spurs for specific applications. See the DES Timing Adjust (Addr: 7h). As the DES Timing Adjust is programmed from 0d to 127d, the magnitude of the Fs/2-Fin timing interleaving spur will decrease to a local minimum and then increase again. The default, nominal setting of 64d may or may not coincide with this local minimum. The user may manually skew the global timing to achieve the lowest possible timing interleaving spur.

# 5.3.1.5 Sampling Clock Phase (Aperture) Delay Adjust

**NOTE** 

Sampling Clock Phase Adjust cannot be used in DES mode (DESI, DESQ, DESIQ or DESCLKIQ) at CLK frequencies above 1600 MHz.

The sampling clock (CLK) phase may be delayed internally to the ADC up to 825 ps in ECM. This feature is intended to help the system designer remove small imbalances in clock distribution traces at the board level when multiple ADCs are used, or to simplify complex system functions such as beam steering for phase array antennas.

Additional delay in the clock path also creates additional jitter when using the sampling clock phase adjust. Because the sampling clock phase adjust delays all clocks, including the DCLKs and output data, the user is strongly advised to use the minimal amount of adjustment and verify the net benefit of this feature in his system before relying on it.

Using this feature at its maximum setting, for the maximum sampling clock rate, may affect the integrity of the sampling clock on chip. Therefore, it is not recommended to do so. The maximum setting for the coarse adjust is 825ps. The period for the maximum sampling clock rate of is 555ps, so it should not be necessary to exceed this value in any case.

# 5.3.2 Output Control and Adjust

There are several features and configurations for the output of the ADC12D1800 so that it may be used in many different applications. This section covers DDR clock phase, LVDS output differential and common-mode voltage, output formatting, Demux/Non-demux Mode, Test Pattern Mode, and Time Stamp.

#### 5.3.2.1 DDR Clock Phase

The ADC12D1800 output data is always delivered in Double Data Rate (DDR). With DDR, the DCLK frequency is half the data rate and data is sent to the outputs on both edges of DCLK; see Figure 5-1. The DCLK-to-Data phase relationship may be either  $0^{\circ}$  or  $90^{\circ}$ . For  $0^{\circ}$  Mode, the Data transitions on each edge of the DCLK. Any offset from this timing is  $t_{OSK}$ ; see Section 4.13 for details. For  $90^{\circ}$  Mode, the DCLK transitions in the middle of each Data cell. Setup and hold times for this transition,  $t_{SU}$  and  $t_{H}$ , may also be found in Section 4.13. The DCLK-to-Data phase relationship may be selected via the DDRPh Pin in Non-ECM (see Section 5.5.1.1.3) or the DPS bit in the Configuration Register (Addr: 0h; Bit: 14) in ECM.

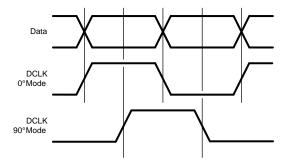


Figure 5-1. DDR DCLK-to-Data Phase Relationship

#### 5.3.2.2 LVDS Output Differential Voltage

The ADC12D1800 is available with a selectable higher or lower LVDS output differential voltage. This parameter is  $V_{OD}$  and may be found in Section 4.11. The desired voltage may be selected via the OVS Bit (Addr: 0h, Bit 13). For many applications, in which the LVDS outputs are very close to an FPGA on the same board, for example, the lower setting is sufficient for good performance; this will also reduce the possibility for EMI from the LVDS outputs to other signals on the board. See Section 5.6.1 for more information.

#### 5.3.2.3 LVDS Output Common-Mode Voltage

The ADC12D1800 is available with a selectable higher or lower LVDS output common-mode voltage. This parameter is  $V_{OS}$  and may be found in Section 4.11. See Section 5.5.1.1.11 for information on how to select the desired voltage.

# 5.3.2.4 Output Formatting

The formatting at the digital data outputs may be either offset binary or two's complement. The default formatting is offset binary, but two's complement may be selected via the 2SC Bit (Addr: 0h, Bit 4); see Section 5.6.1 for more information.

# 5.3.2.5 Test Pattern Mode

The ADC12D1800 can provide a test pattern at the four output buses independently of the input signal to aid in system debug. In Test Pattern Mode, the ADC is disengaged and a test pattern generator is connected to the outputs, including ORI and ORQ. The test pattern output is the same in DES Mode or Non-DES Mode. Each port is given a unique 12-bit word, alternating between 1's and 0's. When the part is programmed into the Demux Mode, the test pattern's order is described in Table 5-2. If the I- or Q-channel is powered down, the test pattern will not be output for that channel.



Table 5-2. Test Pattern by Output Port in Demux Mode

TIME	Qd	ld	Q	I	ORQ	ORI	COMMENTS
T0	000 <b>h</b>	004 <b>h</b>	008 <b>h</b>	010 <b>h</b>	0 <b>b</b>	0 <b>b</b>	
T1	FFFh	FFB <b>h</b>	FF7h	FEFh	1 <b>b</b>	1 <b>b</b>	Pattern
T2	000 <b>h</b>	004 <b>h</b>	008 <b>h</b>	010 <b>h</b>	0 <b>b</b>	0 <b>b</b>	sequence
Т3	FFFh	FFBh	FF7h	FEFh	1 <b>b</b>	1 <b>b</b>	n
T4	000 <b>h</b>	004 <b>h</b>	008 <b>h</b>	010 <b>h</b>	0 <b>b</b>	0 <b>b</b>	
T5	000 <b>h</b>	004 <b>h</b>	008 <b>h</b>	010 <b>h</b>	0 <b>b</b>	0 <b>b</b>	
T6	FFFh	FFBh	FF7h	FEFh	1 <b>b</b>	1 <b>b</b>	Pattern
T7	000 <b>h</b>	004 <b>h</b>	008 <b>h</b>	010 <b>h</b>	0 <b>b</b>	0 <b>b</b>	sequence
T8	FFFh	FFBh	FF7h	FEFh	1 <b>b</b>	1 <b>b</b>	n+1
Т9	000 <b>h</b>	004 <b>h</b>	008 <b>h</b>	010 <b>h</b>	0 <b>b</b>	0 <b>b</b>	
T10	000 <b>h</b>	004 <b>h</b>	008 <b>h</b>	010 <b>h</b>	0 <b>b</b>	0 <b>b</b>	
T11	FFFh	FFBh	FF7h	FEFh	1 <b>b</b>	1 <b>b</b>	Pattern
T12	000 <b>h</b>	004 <b>h</b>	008 <b>h</b>	010 <b>h</b>	0 <b>b</b>	0 <b>b</b>	sequence n+2
T13							

When the part is programmed into the Non-Demux Mode, the test pattern's order is described in Table 5-3.

Table 5-3. Test Pattern by Output Port in Non-Demux Mode

TIME	Q	I	ORQ	ORI	COMMENTS
T0	000 <b>h</b>	004 <b>h</b>	0 <b>b</b>	0 <b>b</b>	
T1	000 <b>h</b>	004 <b>h</b>	<b>d</b> 0	0 <b>b</b>	
T2	FFFh	FFB <b>h</b>	1 <b>b</b>	1 <b>b</b>	
T3	FFFh	FFB <b>h</b>	1 <b>b</b>	1 <b>b</b>	
T4	000 <b>h</b>	004 <b>h</b>	0 <b>b</b>	0 <b>b</b>	Pattern
T5	FFFh	FFB <b>h</b>	1 <b>b</b>	1 <b>b</b>	sequence <b>n</b>
T6	000 <b>h</b>	004 <b>h</b>	<b>d</b> 0	0 <b>b</b>	
T7	FFFh	FFB <b>h</b>	1 <b>b</b>	1 <b>b</b>	
T8	FFFh	FFB <b>h</b>	1 <b>b</b>	1 <b>b</b>	
Т9	FFFh	FFB <b>h</b>	1 <b>b</b>	1 <b>b</b>	
T10	000 <b>h</b>	004 <b>h</b>	0 <b>b</b>	0 <b>b</b>	
T11	000 <b>h</b>	004 <b>h</b>	0 <b>b</b>	0 <b>b</b>	Pattern
T12	FFFh	FFB <b>h</b>	1 <b>b</b>	1 <b>b</b>	sequence
T13	FFFh	FFB <b>h</b>	1 <b>b</b>	1 <b>b</b>	n+1
T14		•••			

# **5.3.2.6 Time Stamp**

The Time Stamp feature enables the user to capture the timing of an external trigger event, relative to the sampled signal. When enabled via the TSE Bit (Addr: 0h; Bit: 3), the LSB of the digital outputs (DQd, DQ, DId, DI) captures the trigger information. In effect, the 12-bit converter becomes an 11-bit converter and the LSB acts as a 1-bit converter with the same latency as the 11-bit converter. The trigger should be applied to the DCLK\_RST input. It may be asynchronous to the ADC sampling clock.

#### 5.3.3 Calibration Feature

The ADC12D1800 calibration must be run to achieve specified performance. The calibration procedure is exactly the same regardless of how it was initiated or when it is run. Calibration trims the analog input differential termination resistors, the CLK input resistor, and sets internal bias currents which affect the linearity of the converter. This minimizes full-scale error, offset error, DNL and INL, which results in the maximum dynamic performance, as measured by: SNR, THD, SINAD (SNDR) and ENOB.

#### 5.3.3.1 Calibration Control Pins and Bits

Table 5-4 is a summary of the pins and bits used for calibration. See Section 3.1 for complete pin information and Figure 4-7 for the timing diagram.

**FUNCTION** PIN (BIT) NAME CAL Initiate calibration (Addr: 0h; Bit 15) (Calibration) CalDly V4 Select power-on calibration delay (Calibration Delay) (Addr: 4h) Calibration Adjust Adjust calibration sequence CalRun **B**5 Indicates while calibration is running (Calibration Running) Rtrim+/-C1/D2 External resistor used to calibrate analog and CLK inputs (Input termination trim resistor) Rext+/-C3/D3 External resistor used to calibrate internal linearity (External Reference resistor)

**Table 5-4. Calibration Pins** 

#### 5.3.3.2 How to Execute a Calibration

Calibration may be initiated by holding the CAL pin low for at least  $t_{CAL\_L}$  clock cycles, and then holding it high for at least another  $t_{CAL\_H}$  clock cycles, as defined in Section 4.15. The minimum  $t_{CAL\_L}$  and  $t_{CAL\_H}$  input clock cycle sequences are required to ensure that random noise does not cause a calibration to begin when it is not desired. The time taken by the calibration procedure is specified as  $t_{CAL}$ . The CAL Pin is active in both ECM and Non-ECM. However, in ECM, the CAL Pin is logically OR'd with the CAL Bit, so both the pin and bit are required to be set low before executing another calibration via either pin or bit.

#### 5.3.3.3 Power-on Calibration

For standard operation, power-on calibration begins after a time delay following the application of power, as determined by the setting of the CalDly Pin and measured by t<sub>CalDly</sub> (see Section 4.15). This delay allows the power supply to come up and stabilize before the power-on calibration takes place. The best setting (short or long) of the CalDly Pin depends upon the settling time of the power supply.

It is strongly recommended to set CalDly Pin (to either logic-high or logic-low) before powering the device on since this pin affects the power-on calibration timing. This may be accomplished by setting CalDly via an external  $1k\Omega$  resistor connected to GND or  $V_A$ . If the CalDly Pin is toggled while the device is powered-on, it can execute a calibration even though the CAL Pin/Bit remains logic-low.

The power-on calibration will be not be performed if the CAL pin is logic-high at power-on. In this case, the calibration cycle will not begin until the on-command calibration conditions are met. The ADC12D1800 will function with the CAL pin held high at power up, but no calibration will be done and performance will be impaired.

If it is necessary to toggle the CalDly Pin during the system power up sequence, then the CAL Pin/Bit must be set to logic-high before the toggling and afterwards for 10<sup>9</sup> Sampling Clock cycles. This will prevent the power-on calibration, so an on-command calibration must be executed or the performance will be impaired.



#### 5.3.3.4 On-Command Calibration

In addition to the power-on calibration, it is recommended to execute an on-command calibration whenever the settings or conditions to the device are altered significantly, in order to obtain optimal parametric performance. Some examples include: changing the FSR via ECM, power-cycling either channel, and switching into or out of DES Mode. For best performance, it is also recommended that an on-command calibration be run 20 seconds or more after application of power and whenever the operating temperature changes significantly, relative to the specific system performance requirements.

Due to the nature of the calibration feature, it is recommended to avoid unnecessary activities on the device while the calibration is taking place. For example, do not read or write to the Serial Interface or use the DCLK Reset feature while calibrating the ADC. Doing so will impair the performance of the device until it is re-calibrated correctly. It is recommended to not apply a strong narrow-band signal to the analog inputs during calibration. This may impair the accuracy of the calibration; broad spectrum noise is Acceptable.

### 5.3.3.5 Calibration Adjust

The sequence of the calibration event itself may be adjusted. This feature can be used if a shorter calibration time than the default is required; see  $t_{CAL}$  in Section 4.15. However, the performance of the device, when using this feature is not ensured.

The calibration sequence may be adjusted via CSS (Addr: 4h, Bit 14). The default setting of CSS = 1b executes both  $R_{IN}$  and  $R_{IN\_CLK}$  Calibration (using Rtrim) and internal linearity Calibration (using Rext). Executing a calibration with CSS = 0b executes only the internal linearity Calibration. The first time that Calibration is executed, it must be with CSS = 1b to trim  $R_{IN}$  and  $R_{IN\_CLK}$ . However, once the device is at its operating temperature and  $R_{IN}$  has been trimmed at least one time, it will not drift significantly. To save time in subsequent calibrations, trimming  $R_{IN}$  and  $R_{IN\_CLK}$  may be skipped, i.e. by setting CSS = 0b.

# 5.3.3.6 Read/Write Calibration Settings

When the ADC performs a calibration, the calibration constants are stored in an array which is accessible via the Calibration Values register (Addr: 5h). To save the time which it takes to execute a calibration,  $t_{CAL}$ , or to allow for re-use of a previous calibration result, these values can be read from and written to the register at a later time. For example, if an application requires the same input impedance,  $R_{IN}$ , this feature can be used to load a previously determined set of values. For the calibration values to be valid, the ADC must be operating under the same conditions, including temperature, at which the calibration values were originally determined by the ADC.

To read calibration values **from the SPI**, do the following:

- 1. Set ADC to desired operating conditions.
- 2. Set SSC (Addr: 4h, Bit 7) to 1.
- 3. Read exactly 240 times the Calibration Values register (Addr: 5h). The register values are R0, R1, R2... R239 where R0 is a dummy value. The contents of R<239:1> should be stored.
- 4. Set SSC (Addr: 4h, Bit 7) to 0.
- 5. Continue with normal operation.

To write calibration values to the SPI, do the following:

- 1. Set ADC to operating conditions at which Calibration Values were previously read.
- 2. Set SSC (Addr: 4h, Bit 7) to 1.
- 3. Write exactly 239 times the Calibration Values register (Addr: 5h). The registers should be written R1, R2, ..., R239.
- 4. Make two additional dummy writes of 0000h.
- 5. Set SSC (Addr: 4h, Bit 7) to 0.
- Continue with normal operation.

# 5.3.3.7 Calibration and Power-Down

If PDI and PDQ are simultaneously asserted during a calibration cycle, the ADC12D1800 will immediately power down. The calibration cycle will continue when either or both channels are powered back up, but the calibration will be compromised due to the incomplete settling of bias currents directly after power up. Therefore, a new calibration should be executed upon powering the ADC12D1800 back up. In general, the ADC12D1800 should be recalibrated when either or both channels are powered back up, or after one channel is powered down. For best results, this should be done after the device has stabilized to its operating temperature.

# 5.3.3.8 Calibration and the Digital Outputs

During calibration, the digital outputs (including DI, DId, DQ, DQd and OR) are set logic-low, to reduce noise. The DCLK runs continuously during calibration. After the calibration is completed and the CalRun signal is logic-low, it takes an additional 60 Sampling Clock cycles before the output of the ADC12D1800 is valid converted data from the analog inputs. This is the time it takes for the pipeline to flush, as well as for other internal processes.

# 5.3.4 Power Down

On the ADC12D1800, the I- and Q-channels may be powered down individually. This may be accomplished via the control pins, PDI and PDQ, or via ECM. In ECM, the PDI and PDQ pins are logically OR'd with the Control Register setting. See Section 5.5.1.1.6 and Section 5.5.1.1.7 for more information.



#### 5.4 Device Functional Modes

The ADC12D1800RF has two functional modes for sampling the input signal, DES mode and Non-DES mode and two mode to output sample data, Demux mode and Non-Demux Mode.

#### 5.4.1 DES/Non-DES Mode

The ADC12D1800 can operate in Dual-Edge Sampling (DES) or Non-DES Mode. The DES Mode allows for a single analog input to be sampled by both I- and Q-channels. One channel samples the input on the rising edge of the sampling clock and the other samples the same input signal on the falling edge of the sampling clock. A single input is thus sampled twice per clock cycle, resulting in an overall sample rate of twice the sampling clock frequency, e.g. 3.6 GSPS with a 1.8 GHz sampling clock. Since DES Mode uses both I- and Q-channels to process the input signal, both channels must be powered up for the DES Mode to function properly.

In Non-ECM, only the I-input may be used for the DES Mode input. See *Section 5.5.1.1.1* for information on how to select the DES Mode. In ECM, either the I- or Q-input may be selected by first using the DES bit (Addr: 0h, Bit 7) to select the DES Mode. The DEQ Bit (Addr: 0h, Bit: 6) is used to select the Q-input, but the I-input is used by default. Also, both I- and Q-inputs may be driven externally, i.e. DESIQ Mode, by using the DIQ bit (Addr: 0h, Bit 5). See *Section 6.1.1* for more information about how to drive the ADC in DES Mode.

The DESIQ Mode results in the best bandwidth. In general, the bandwidth decreases from Non-DES Mode to DES Mode (specifically, DESI or DESQ) because both channels are sampling off the same input signal and non-ideal effects introduced by interleaving the two channels lower the bandwidth. Driving both I- and Q-channels externally (DESIQ Mode) results in better bandwidth for the DES Mode because each channel is being driven, which reduces routing losses (increases bandwidth).

In the DES Mode, the outputs must be carefully interleaved in order to reconstruct the sampled signal. If the device is programmed into the 1:4 Demux DES Mode, the data is effectively demultiplexed by 1:4. If the sampling clock is 1.8 GHz, the effective sampling rate is doubled to 3.6 GSPS and each of the 4 output buses has an output rate of 900 MSPS. All data is available in parallel. To properly reconstruct the sampled waveform, the four bytes of parallel data that are output with each DCLK must be correctly interleaved. The sampling order is as follows, from the earliest to the latest: DQd, DId, DQ, DI. See Figure 4-4. If the device is programmed into the Non-Demux DES Mode, two bytes of parallel data are output with each edge of the DCLK in the following sampling order, from the earliest to the latest: DQ, DI. See Figure 4-5.

### 5.4.2 Demux/Non-Demux Mode

The ADC12D1800 may be in one of two demultiplex modes: Demux Mode or Non-Demux Mode (also sometimes referred to as 1:1 Demux Mode). In Non-Demux Mode, the data from the input is simply output at the sampling rate on one 12-bit bus. In Demux Mode, the data from the input is output at half the sampling rate, on twice the number of buses. Demux/Non-Demux Mode may only be selected by the NDM pin; see Section 5.5.1.1.2. In Non-DES Mode, the output data from each channel may be demultiplexed by a factor of 1:2 (1:2 Demux Non-DES Mode) or not demultiplexed (Non-Demux Non-DES Mode). In DES Mode, the output data from both channels interleaved may be demultiplexed (1:4 Demux DES Mode) or not demultiplexed (Non-Demux DES Mode).



### 5.5 Programming

#### 5.5.1 Control Modes

The ADC12D1800 may be operated in one of two control modes: Non-extended Control Mode (Non-ECM) or Extended Control Mode (ECM). In the simpler Non-ECM (also sometimes referred to as Pin Control Mode), the user affects available configuration and control of the device through the control pins. The ECM provides additional configuration and control options through a serial interface and a set of 16 registers, most of which are available to the customer.

#### 5.5.1.1 Non-Extended Control Mode

In Non-extended Control Mode (Non-ECM), the Serial Interface is not active and all available functions are controlled via various pin settings. Non-ECM is selected by setting the  $\overline{\text{ECE}}$  Pin to logic-high. Note that, for the control pins, "logic-high" and "logic-low" refer to  $V_A$  and GND, respectively. Nine dedicated control pins provide a wide range of control for the ADC12D1800 and facilitate its operation. These control pins provide DES Mode selection, Demux Mode selection, DDR Phase selection, execute Calibration, Calibration Delay setting, Power Down I-channel, Power Down Q-channel, Test Pattern Mode selection, and Full-Scale Input Range selection. In addition to this, two dual-purpose control pins provide for AC/DC-coupled Mode selection and LVDS output common-mode voltage selection. See Table 5-5 for a summary.

Table 5-5. Non-ECM Pin Summary
C-LOW LOGIC-HIGH

PIN NAME	LOGIC-LOW	LOGIC-HIGH	FLOATING
	Dedicate	ed Control Pins	
DES	Non-DES Mode	DES Mode	Not valid
NDM	Demux Mode	Non-Demux Mode	Not valid
DDRPh	0° Mode	90° Mode	Not valid
CAL	See Section 5.	5.1.1.4 section	Not valid
CalDly	Shorter delay	Longer delay	Not valid
PDI	I-channel active	Power Down I-channel	Power Down I-channel
PDQ	Q-channel active	Power Down Q-channel	Power Down Q-channel
TPM	Non-Test Pattern Mode	Test Pattern Mode	Not valid
FSR	Not allowed	Nominal FS input Range	Not valid
	Dual-purp	ose Control Pins	
$V_{CMO}$	AC-coupled operation	Not allowed	DC-coupled operation
$V_{BG}$	Not allowed	Higher LVDS common-mode voltage	Lower LVDS common-mode voltage

# 5.5.1.1.1 Dual Edge Sampling Pin (DES)

The Dual Edge Sampling (DES) Pin selects whether the ADC12D1800 is in DES Mode (logic-high) or Non-DES Mode (logic-low). DES Mode means that a single analog input is sampled by both I- and Q-channels in a time-interleaved manner. One of the ADCs samples the input signal on the rising sampling clock edge (duty cycle corrected); the other ADC samples the input signal on the falling sampling clock edge (duty cycle corrected). In Non-ECM, only the I-input may be used for DES Mode, a.k.a. "DESI Mode". In ECM, the Q-input may be selected via the DEQ Bit (Addr: 0h, Bit: 6), a.k.a. "DESQ Mode". In ECM, both the I- and Q-inputs maybe selected, a.k.a. "DESIQ Mode".

To use this feature in ECM, use the DES bit in the Configuration Register (Addr: 0h; Bit: 7). See Section 5.4.1 for more information.

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### 5.5.1.1.2 Non-Demultiplexed Mode Pin (NDM)

The Non-Demultiplexed Mode (NDM) Pin selects whether the ADC12D1800 is in Demux Mode (logic-low) or Non-Demux Mode (logic-high). In Non-Demux Mode, the data from the input is produced at the sampled rate at a single 12-bit output bus. In Demux Mode, the data from the input is produced at half the sampled rate at twice the number of output buses. For Non-DES Mode, each I- or Q-channel will produce its data on one or two buses for Non-Demux or Demux Mode, respectively. For DES Mode, the selected channel will produce its data on two or four buses for Non-Demux or Demux Mode, respectively.

This feature is pin-controlled only and remains active during both Non-ECM and ECM. See Section 5.4.2 for more information.

### 5.5.1.1.3 Dual Data Rate Phase Pin (DDRPh)

The Dual Data Rate Phase (DDRPh) Pin selects whether the ADC12D1800 is in 0° Mode (logic-low) or 90° Mode (logic-high). The Data is always produced in DDR Mode on the ADC12D1800. The Data may transition either with the DCLK transition (0° Mode) or halfway between DCLK transitions (90° Mode). The DDRPh Pin selects 0° Mode or 90° Mode for both the I-channel: DI- and DId-to-DCLKI phase relationship and for the Q-channel: DQ- and DQd-to-DCLKQ phase relationship.

To use this feature in ECM, use the DPS bit in the Configuration Register (Addr: 0h; Bit: 14). See Section 5.3.2.1 for more information.

### 5.5.1.1.4 Calibration Pin (CAL)

The Calibration (CAL) Pin may be used to execute an on-command calibration or to disable the power-on calibration. The effect of calibration is to maximize the dynamic performance. To initiate an on-command calibration via the CAL pin, bring the CAL pin high for a minimum of  $t_{CAL\_H}$  input clock cycles after it has been low for a minimum of  $t_{CAL\_L}$  input clock cycles. Holding the CAL pin high upon power-on will prevent execution of the power-on calibration. In ECM, this pin remains active and is logically OR'd with the CAL bit.

To use this feature in ECM, use the CAL bit in the Configuration Register (Addr: 0h; Bit: 15). See Section 5.3.3 for more information.

# 5.5.1.1.5 Calibration Delay Pin (CalDly)

The Calibration Delay (CalDly) Pin selects whether a shorter or longer delay time is present, after the application of power, until the start of the power-on calibration. The actual delay time is specified as t<sub>CalDly</sub> and may be found in Section 4.15. This feature is pin-controlled only and remains active in ECM. It is recommended to select the desired delay time prior to power-on and not dynamically alter this selection.

See Section 5.3.3 for more information.

#### 5.5.1.1.6 Power Down I-channel Pin (PDI)

The Power Down I-channel (PDI) Pin selects whether the I-channel is powered down (logic-high) or active (logic-low). The digital data output pins, DI and DId, (both positive and negative) are put into a high impedance state when the I-channel is powered down. Upon return to the active state, the pipeline will contain meaningless information and must be flushed. The supply currents (typicals and limits) are available for the I-channel powered down or active and may be found in Section 4.12. The device should be recalibrated following a power-cycle of PDI (or PDQ).

This pin remains active in ECM. In ECM, either this pin or the PDI bit (Addr: 0h; Bit: 11) in the Control Register may be used to power-down the I-channel. See Section 5.3.4 for more information.



# 5.5.1.1.7 Power Down Q-channel Pin (PDQ)

The Power Down Q-channel (PDQ) Pin selects whether the Q-channel is powered down (logic-high) or active (logic-low). This pin functions similarly to the PDI pin, except that it applies to the Q-channel. The PDI and PDQ pins function independently of each other to control whether each I- or Q-channel is powered down or active.

This pin remains active in ECM. In ECM, either this pin or the PDQ bit (Addr: 0h; Bit: 10) in the Control Register may be used to power-down the Q-channel. See Section 5.3.4 for more information.

#### 5.5.1.1.8 Test Pattern Mode Pin (TPM)

The Test Pattern Mode (TPM) Pin selects whether the output of the ADC12D1800 is a test pattern (logic-high) or the converted analog input (logic-low). The ADC12D1800 can provide a test pattern at the four output buses independently of the input signal to aid in system debug. In TPM, the ADC is disengaged and a test pattern generator is connected to the outputs, including ORI and ORQ. See Section 5.3.2.5 for more information.

# 5.5.1.1.9 Full-Scale Input Range Pin (FSR)

The Full-Scale Input Range (FSR) Pin sets the full-scale input range for both the I- and Q-channel; for the ADC12D1800, only the logic-high setting is available. The input full-scale range is specified as  $V_{\text{IN\_FSR}}$  in Section 4.7. In Non-ECM, the full-scale input range for each I- and Q-channel may not be set independently, but it is possible to do so in ECM. The device must be calibrated following a change in FSR to obtain optimal performance.

To use this feature in ECM, use the Configuration Registers (Addr: 3h and Bh). See Section 5.3.1 for more information.

# 5.5.1.1.10 AC/DC-Coupled Mode Pin (V<sub>CMO</sub>)

The  $V_{CMO}$  Pin serves a dual purpose. When functioning as an output, it provides the optimal common-mode voltage for the DC-coupled analog inputs. When functioning as an input, it selects whether the device is AC-coupled (logic-low) or DC-coupled (floating). This pin is always active, in both ECM and Non-ECM.

# 5.5.1.1.11 LVDS Output Common-mode Pin (V<sub>BG</sub>)

The  $V_{BG}$  Pin serves a dual purpose. When functioning as an output, it provides the bandgap reference. When functioning as an input, it selects whether the LVDS output common-mode voltage is higher (logic-high) or lower (floating). The LVDS output common-mode voltage is specified as  $V_{OS}$  and may be found in Section 4.11. This pin is always active, in both ECM and Non-ECM.

#### 5.5.1.2 Extended Control Mode

In Extended Control Mode (ECM), most functions are controlled via the Serial Interface. In addition to this, several of the control pins remain active. See Table 5-1 for details. ECM is selected by setting the ECE Pin to logic-low. If the ECE Pin is set to logic-high (Non-ECM), then the registers are reset to their default values. So, a simple way to reset the registers is by toggling the ECE pin. Four pins on the ADC12D1800 control the Serial Interface: SCS, SCLK, SDI and SDO. This section covers the Serial Interface. The Register Definitions are located at the end of the datasheet so that they are easy to find, see Section 5.6.1.

#### 5.5.1.2.1 Serial Interface

RUMENTS

The ADC12D1800 offers a Serial Interface that allows access to the sixteen control registers within the device. The Serial Interface is a generic 4-wire (optionally 3-wire) synchronous interface that is compatible with SPI type interfaces that are used on many micro-controllers and DSP controllers. Each serial interface access cycle is exactly 24 bits long. A register-read or register-write can be accomplished in one cycle. The signals are defined in such a way that the user can opt to simply join SDI and SDO signals in his system to accomplish a single, bidirectional SDI/O signal. A summary of the pins for this interface may be found in Table 5-6. See Figure 4-8 for the timing diagram and Section 4.14 for timing specification details. Control register contents are retained when the device is put into power-down mode. If this feature is unused, the SCLK, SDI, and SCS pins may be left floating because they each have an internal pull-up.

PIN NAME C4 SCS (Serial Chip Select bar) C5 SCLK (Serial Clock) В4 SDI (Serial Data In) АЗ SDO (Serial Data Out)

Table 5-6. Serial Interface Pins

SCS: Each assertion (logic-low) of this signal starts a new register access, i.e. the SDI command field must be ready on the following SCLK rising edge. The user is required to de-assert this signal after the 24th clock. If the SCS is de-asserted before the 24th clock, no data read/write will occur. For a read operation, if the SCS is asserted longer than 24 clocks, the SDO output will hold the D0 bit until SCS is de-asserted. For a write operation, if the SCS is asserted longer than 24 clocks, data write will occur normally through the SDI input upon the 24th clock. Setup and hold times, t<sub>SCS</sub> and t<sub>HCS</sub>, with respect to the SCLK must be observed. SCS must be toggled in between register access cycles.

SCLK: This signal is used to register the input data (SDI) on the rising edge; and to source the output data (SDO) on the falling edge. The user may disable the clock and hold it at logic-low. There is no minimum frequency requirement for SCLK; see f<sub>SCLK</sub> in Section 4.14 for more details.

SDI: Each register access requires a specific 24-bit pattern at this input, consisting of a command field and a data field. If the SDI and SDO wired are shared (3-wire mode), then during read operations it is necessary to tri-state the master which is driving SDI while the data field is being output by the ADC on SDO. The master must be at TRI-STATE before the falling edge of the 8th clock. If SDI and SDO are not shared (4-wire mode), then this is not necessary. Setup and hold times, t<sub>SH</sub> and t<sub>SSU</sub>, with respect to the SCLK must be observed.

SDO: This output is normally at TRI-STATE and is driven only when SCS is asserted, the first 8 bits of command data have been received and it is a READ operation. The data is shifted out, MSB first, starting with the 8th clock's falling edge. At the end of the access, when SCS is de-asserted, this output is at TRI-STATE once again. If an invalid address is accessed, the data sourced will consist of all zeroes. If it is a read operation, there will be a bus turnaround time, t<sub>BSU</sub>, from when the last bit of the command field was read in until the first bit of the data field is written out.

Table 5-7 shows the Serial Interface bit definitions.

Table 5-7. Command and Data Field Definitions

BIT NO.	NAME	COMMENTS
1	Read/Write (R/W)	1 <b>b</b> indicates a read operation 0 <b>b</b> indicates a write operation
2-3	Reserved	Bits must be set to 10b
4-7	A<3:0>	16 registers may be addressed. The order is MSB first
8	X	This is a does not matter bit.
9-24	D<15:0>	Data written to or read from addressed register

The serial data protocol is shown for a read and write operation in Figure 5-2 and Figure 5-3, respectively.

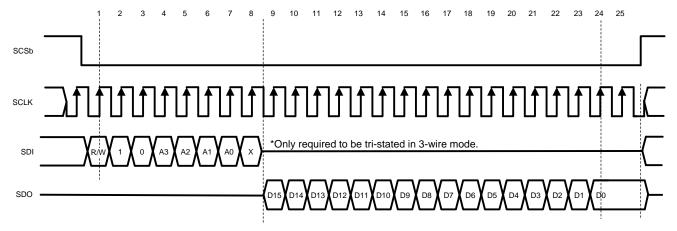


Figure 5-2. Serial Data Protocol - Read Operation

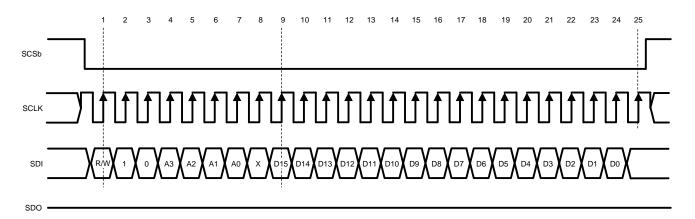


Figure 5-3. Serial Data Protocol - Write Operation



# 5.6 Register Maps

# 5.6.1 Register Definitions

Eleven read/write registers provide several control and configuration options in the Extended Control Mode. These registers have no effect when the device is in the Non-extended Control Mode. Each register description below also shows the Power-On Reset (POR) state of each control bit. See Table 5-8 for a summary. For a description of the functionality and timing to read/write the control registers, see Section 5.5.1.2.1.

**Special Note:** Register 6h must be written to 1C00h for the device to perform at full rated performance for Fclk > 1.6GHz.

Table 5-8. Register Addresses

А3	A2	A1	A0	HEX	REGISTER ADDRESSED
0	0	0	0	0 <b>h</b>	Configuration Register 1
0	0	0	1	1h	Reserved
0	0	1	0	2h	I-channel Offset
0	0	1	1	3h	I-channel Full-Scale Range
0	1	0	0	4h	Calibration Adjust
0	1	0	1	5 <b>h</b>	Calibration Values
0	1	1	0	6 <b>h</b>	Bias Adjust
0	1	1	1	7h	DES Timing Adjust
1	0	0	0	8 <b>h</b>	Reserved
1	0	0	1	9 <b>h</b>	Reserved
1	0	1	0	Ah	Q-channel Offset
1	0	1	1	Bh	Q-channel Full-Scale Range
1	1	0	0	Ch	Aperture Delay Coarse Adjust
1	1	0	1	Dh	Aperture Delay Fine Adjust
1	1	1	0	Eh	AutoSync
1	1	1	1	Fh	Reserved



# Table 5-9. Configuration Register 1

Addr: 0	h (0000	b)												Р	OR state:	: <b>2000</b> h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name	CAL	DPS	ovs	TPM	PDI	PDQ	Res	LFS	DES	DEQ	DIQ	2SC	TSE		Res	Į.
POR	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0
Bit 15	upo cal	on comp	letion of This bit	the calib	ration. T	herefore	, the use	er must r	eset this	bit to 0k	and the	en set it t	to 1 <b>b</b> aga	ain to e	automation xecute and o execute	other
Bit 14															ship and 0°DDR M	
Bit 13									age level OD in Sec				luding D	ata, OR	, and DC	LK. 0 <b>b</b>
Bit 12	and	d OR ou	tputs. Wl		o 0 <b>b</b> , the	e device	will cont	inually o	utput the						ne digital the analo	
Bit 11									hannel is bit or the						e I-chann	el is
Bit 10									Q-chann this bit o						, the Q-ch CM.	nannel
Bit 9	Re	served.	Must be	set to 0k	).											
Bit 8	LF	S: Low-F	requenc	y Select	. If the sa	ampling	clock (C	LK) is at	or below	/ 300 MF	dz, set tł	nis bit to	1 <b>b</b> for in	nproved	performa	ance.
Bit 7									o 0 <b>b</b> , the 5.4.1 for				e Non-D	ES Mod	le; when i	it is set
Bit 6									ce is in [ <b>b</b> selects			oit select	s the inp	ut that t	he device	e will
Bit 5	the Mo	device.	If the bit <7:5> mu	is left at	its defa	ult 0 <b>b</b> , th	ne I- and	Q-inputs	s remain	electrica	ally sepa	rate. To	operate	the dev	outs internice in DEction 5.4.	SIQ
Bit 4				ement ou ro's Com			ault setti	ng of 0 <b>b</b> ,	the data	a is outp	ut in Offs	set Binar	y format	; when	set to 1 <b>b</b> ,	the
Bit 3				nable. Fon 5.3.2						np featur	e is not	enabled	; when s	et to 1 <b>b</b>	, the feat	ure is
Bits 2:0	Re	served.	Must be	set as sh	nown.											

# Table 5-10. Reserved

Addr: 1	h (0001	b)												РО	R state:	2A0Eh
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name	Res															
POR	0	0 0 1 0 1 0 1 0 0 0 0 1 1 0														
Bits 15:																



# Table 5-11. I-channel Offset Adjust

Addr: 2	POR 0 0 0 0 0 0 0 0 0  Bits 15:13 Reserved. Must be set to 0b.  Bit 12 OS: Offset Sign. The default setting of 0b incurs a part this bet to 1b incurs a negative offset of the set may be set 11:0 OM(11:0): Offset Magnitude. These bits determine						PC							: 0000h		
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name		Res	1.	os		Į.				OM(	11:0)	•	1.			
POR	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Bits 15:	13	Reserved.	Must be	set to 0k	<b>)</b> .											
Bit 12		OS: Offset Sign. The default setting of 0 <b>b</b> incurs a positive offset of a magnitude set by Bits 11:0 to the ADC output. Setting this bet to 1 <b>b</b> incurs a negative offset of the set magnitude.  OM(11:0): Offset Magnitude. These bits determine the magnitude of the offset set at the ADC output (straight binary coding).														
Bits 11:0 OM(11:0): Offset Magnitude. These bits determine the magnitude of the offset set at the ADC output (straight binary coding). The range is from 0 mV for OM(11:0) = 0d to 45 mV for OM(11:0) = 4095d in steps of ~11 µV. Monotonicity is specified by																
	1	Code						Offs	et [mV]							
		0000 0000 0000 (default) 0														
		1000 0000	0000					22.5								
	1111 1111 1111 45															

# Table 5-12. I-channel Full Scale Range Adjust

					able .	)- I Z. I-(	Ciiaiiii	zı ı uıı	Scale	ivarige	Aujus	<b>5</b> 1				
Addr: 3	h (0011	b)												PC	OR state	: 4000h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name	Res		*	•			•		FM(14:0)	)		·		•		
POR	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Bit 15																
Bit 15  Reserved. Must be set to 0b.  Bits 14:0  FM(14:0): FSR Magnitude. These bits increase the ADC full-scale range magnitude (straight binary coding.) The allowable range is from 800 mV (16384d) to 1000 mV (32767d) with the default setting at 800 mV (16384d). Monotonicity is specified by design only for the 9 MSBs. A greater range of FSR values is available in ECM, i.e. FSR values above 800 mV. See V <sub>IN_FSR</sub> in Section 4.7 for characterization details.										ified by						
	Code FSR [mV]															
	10	100 0000 0000 0000 (default) 800														
	111 1111 1111 1111 1100															

Product Folder Links: ADC12D1800



# Table 5-13. Calibration Adjust

Addr: 4	h (010	0b)												РО	R state:	DF4Bh
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name	Res	CSS		1	R	es			SSC				Res			
POR	1	1	0	1	1	1	1	1	0	1	0	0	1	0	1	1
Bit 15	R	eserved.	Must be	set as s	hown.											
Bit 14	e ca m	SS: Calib ements to alibration oust be co IN calibrat	nomina sequenc mpleted	al values e: do no at least	, do R <sub>IN</sub> t reset R one time	Calibration of the contract of	on, do in nominal SS = 1 <b>b</b> 1	ternal lin value, sk to calibra	iearity Ca kip R <sub>IN</sub> ca te R <sub>IN</sub> . S	alibratior alibratior	n. Settino n, do inte	g CSS = ernal line	0 <b>b</b> seled arity Cal	ts the fo	Ílowing The cali	bration
Bits 13:	8 R	eserved.	Must be	set as s	hown.											
Bit 7	n	Reserved. Must be set as shown.  SSC: SPI Scan Control. Setting this control bit to 1b allows the calibration values, stored in Addr: 5h, to be read/written. When not reading/writing the calibration values, this control bit should left at its default 0b setting. See Section 5.3.3 for more information.														
Bits 6:0	R	eserved.	Must be	set as s	hown.											

# **Table 5-14. Calibration Values**

Addr: 5	ih (0101	b)												POI	R state:	XXXXh
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name	SS(15:0)															
POR	Χ	X X X X X X X X X X X X X X X X X X X														
Bits 15:	Bits 15:0 SS(15:0): SPI Scan. When the ADC performs a self-calibration, the values for the calibration are stored in this register and may be read from/ written to it. Set SSC (Addr: 4h, Bit 7) to read/write. See Section 5.3.3 for more information.															

# Table 5-15. Bias Adjust

Addr: 6	Sh (011	0b)												РО	R state:	1C20h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name		MPA(15:0)														
POR	0	0 0 0 1 1 1 0 0 0 0 1 0 0 0 0														
Bits 15:	-	PA(15:0): <b>6GHz.</b>	: Max Po	wer Adjı	ıst. <b>This</b>	registe	r must b	e writte	n to 1C0	00h to ac	chieve f	ull rated	perforn	nance fo	r Fclk >	)

# Table 5-16. DES Timing Adjust

Addr: 7	'h (0111	b)												PC	OR state	: 8140h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name																
POR	1 0 0 0 0 0 1 0 1 0 0 0 0															
Bits 15:	the	A(6:0): E e rising e ection 5.3	dge of th	ne sampl	ing clock	may be	adjuste	d; the au	itomatic							e to
Bits 8:0	Re	served. I	Must be	set as sl	nown.											



# Table 5-17. Reserved

Addr: 8	3h (1000	)b)												PC	OR state	: 0000h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name								R	es							
POR	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Bits 15:	0 Re	eserved.	Must be	set as sl	nown.											

# Table 5-18. Reserved

Addr: 9	h (1001	lb)												PC	OR state	: 0000h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name								R	es							
POR	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Bits 15:0	0 Re	served.	Must be	set as sl	hown.	•		•	•		•					

# Table 5-19. Q-channel Offset Adjust

Addr: A	Ah (1	010b)												PC	OR state	: <b>0000</b> h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name		Res	*	os				•	•	OM(	11:0)		•			
POR	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Bits 15:	13	Reserved.	Must be	set to 0k	<b>)</b> .											
Bit 12		5														
Bits 11:		The range	his bet to 1b incurs a negative offset of the set magnitude.  OM(11:0): Offset Magnitude. These bits determine the magnitude of the offset set at the ADC output (straight binary coding). The range is from 0 mV for OM(11:0) = 0d to 45 mV for OM(11:0) = 4095d in steps of ~11 $\mu$ V. Monotonicity is specified by design only for the 9 MSBs.													
		Code						Offs	et [mV]							
		0000 0000	0000 (d	efault)				0								
		1000 0000	0000					22.5								
		1111 1111	1111					45								

# Table 5-20. Q-channel Full-Scale Range Adjust

Addr: E	3h (10	011b)												PC	OR state	: 4000h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name	Res	s						•	FM(14:0	)						
POR	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Bit 15		Reserved. Must be set to 0b.														
Bits 14:		Reserved. Must be set to 0b.  FM(14:0): FSR Magnitude. These bits increase the ADC full-scale range magnitude (straight binary coding.) The allowable range is from 800 mV (16384d) to 1000 mV (32767d) with the default setting at 800 mV (16384d). Monotonicity is specified by design only for the 9 MSBs. A greater range of FSR values is available in ECM, i.e. FSR values above 800 mV. See V <sub>IN_FSR</sub> in Section 4.7 for characterization details.														
		Code						FSR	[mV]							
		100 0000 0	000 000	00 (defau	lt)			800								
		111 1111 1	1111 111	1				1000	)							



# Table 5-21. Aperture Delay Coarse Adjust

Addr: 0	Ch (1100	)b)												PC	R state	: 0004h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name				•		CAM	(11:0)						STA	DCC	R	es
POR	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0

Aperture Delay Adjust feature cannot be used in DES mode (DESI, DESQ, DESIQ or DESCLKIQ) for CLK frequencies above 1600 MHz.

Using the t<sub>AD</sub> Adjust feature at its maximum setting, for the maximum sampling clock rate, may affect the integrity of the sampling clock on chip. Therefore, it is not recommended to do so. The maximum setting for the coarse adjust is 825ps. The period for the maximum sampling clock rate of is 555ps, so it should not be necessary to exceed this value in any case.

Bits 15:4	CAM(11:0): Coarse Adjust Magnitude. This 12-bit value determines the amount of delay that will be applied to the input CLK signal. The range is 0 ps delay for CAM(11:0) = 0d to a maximum delay of 825 ps for CAM(11:0) = 2431d (±95 ps due to PVT variation) in steps of ~340 fs. For code CAM(11:0) = 2432d and above, the delay saturates and the maximum delay applies. Additional, finer delay steps are available in register Dh. The STA (Bit 3) must be selected to enable this function.
Bit 3	STA: Select t <sub>AD</sub> Adjust. Set this bit to 1 <b>b</b> to enable the t <sub>AD</sub> adjust feature, which will make both coarse and fine adjustment settings, i.e. CAM(11:0) and FAM(5:0), available.
Bit 2	DCC: Duty Cycle Correct. This bit can be set to 0b to disable the automatic duty-cycle stabilizer feature of the chip. This feature is enabled by default.
Bits 1:0	Reserved. Must be set to 0b.

# **Table 5-22. Aperture Delay Fine Adjust**

Addr: [	Dh (1101	b)												PC	R state	0000h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name			FAM	(5:0)			R	es				R	es			
POR	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

Aperture Delay Adjust feature cannot be used in DES mode (DESI, DESQ, DESIQ or DESCLKIQ) for CLK frequencies above 1600 MHz.

Using the t<sub>AD</sub> Adjust feature at its maximum setting, for the maximum sampling clock rate, may affect the integrity of the sampling clock on chip. Therefore, it is not recommended to do so. The maximum setting for the coarse adjust is 825ps. The period for the maximum sampling clock rate of is 555ps, so it should not be necessary to exceed this value in any case.

Bits 15:10	the input CLK w	Aperture Adjust Maghen the Clock Phase (5:0) = 0 <b>d</b> to 2.3 ps d	se Adjust fe	ature is enabled via	a STA (Addr:	Ch, Bit 3). The	range is st	raight binary t	
Bits 9:0	Reserved. Must	be set as shown.							



# Table 5-23. AutoSync

Addr: E	Eh (1	110b)												P	OR state	: 0003h
Bit	15	5 14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name					DRC(8:0	)				R	es	SP	(1:0)	ES	DOC	DR
POR	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	1
Bits 15:		DRC(8:0): Delay Reference Clock (9:0). These bits may be used to increase the delay on the input reference clock when synchronizing multiple ADCs. The minimum delay is 0s (0d) to 1000 ps (319d). The delay remains the maximum of 1000 ps for any codes above or equal to 639d. See Section 6.1.4 for more information.  Reserved. Must be set as shown.														
Bits 6:5	,															
Bits 4:3		Reserved. Must be set as shown.  SP(1:0): Select Phase. These bits select the phase of the reference clock which is latched. The codes correspond to the following phase shift:  00 = 0° 01 = 90° 10 = 180° 11 = 270°														
Bit 2		ES: Enab synchroni bit is set t	zed with t	the refere	ence clo	ck comin	g from th									(. If this
Bit 1		DOC: Dis setting of Master or	1 <b>b</b> disabl	es these	output c	Irivers. T	his bit fu									
Bit 0		DR: Disab			ault setti	ng of 1 <b>b</b>	leaves t	he DCL	K_RST fu	unctiona	lity disab	led. Set	this bit t	o 0 <b>b</b> to 6	enable	

# Table 5-24. Reserved<sup>(1)</sup>

Addr: F	Fh (1111	b)												PC	OR state	: 0018h
Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Name		•	•	•				R	es			•	•	•		
POR	0	0	0	0	0	0	0	0	0	0	0	1	1	0	0	0

(1) Bits 15:0 Reserved. This address is read only.

# 6 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

# 6.1 Application Information

# 6.1.1 Analog Inputs

The ADC12D1800 will continuously convert any signal which is present at the analog inputs, as long as a CLK signal is also provided to the device. This section covers important aspects related to the analog inputs including: acquiring the input, driving the ADC in DES Mode, the reference voltage and FSR, out-of-range indication, AC/DC-coupled signals, and single-ended input signals.

# 6.1.1.1 Acquiring the Input

Data is acquired at the rising edge of CLK+ in Non-DES Mode and both the falling and rising edges of CLK+ in DES Mode. The digital equivalent of that data is available at the digital outputs a constant number of sampling clock cycles later for the DI, DQ, DId and DQd output buses, a.k.a. Latency, depending on the demultiplex mode which is selected. See  $t_{LAT}$  in Section 4.13. In addition to the Latency, there is a constant output delay,  $t_{OD}$ , before the data is available at the outputs. See  $t_{OD}$  in Section 4.13 and Figure 4-2 to Figure 4-5.

The output latency versus Demux/Non-Demux Mode is shown in Table 6-1 and Table 6-2, respectively. For DES Mode, note that the I- and Q-channel inputs are available in ECM, but only the I-channel input is available in Non-ECM.

DATA	NON-DES MODE	DES I	MODE
DATA	NON-DES MODE	Q-INPUT <sup>(1)</sup>	I-INPUT
DI	I-input sampled with rise of CLK,	Q-input sampled with rise of CLK,	I-input sampled with rise of CLK,
	34 cycles earlier	34 cycles earlier	34 cycles earlier
DQ	Q-input sampled with rise of CLK,	Q-input sampled with fall of CLK,	I-input sampled with fall of CLK,
	34 cycles earlier	34.5 cycles earlier	34.5 cycles earlier
Dld	I-input sampled with rise of CLK,	Q-input sampled with rise of CLK,	I-input sampled with rise of CLK,
	35 cycles earlier	35 cycles earlier	35 cycles earlier
DQd	Q-input sampled with rise of CLK,	Q-input sampled with fall of CLK,	I-input sampled with fall of CLK,
	35 cycles earlier	35.5 cycles earlier	35.5 cycles earlier

Table 6-1. Output Latency in Demux Mode

Table 6-2. Output Latency in Non-Demux Mode

DATA	NON-DES MODE	DES MODE		
		Q-INPUT <sup>(1)</sup>	I-INPUT	
DI	I-input sampled with rise of CLK, 34 cycles earlier	Q-input sampled with rise of CLK, 34 cycles earlier	I-input sampled with rise of CLK, 34 cycles earlier	
DQ	Q-input sampled with rise of CLK, 34 cycles earlier	Q-input sampled with rise of CLK, 34.5 cycles earlier	I-input sampled with rise of CLK, 34.5 cycles earlier	
Dld	No output; high impedance.			
DQd	No output; high impedance.			

(1) Available in ECM only.

<sup>(1)</sup> Available in ECM only.

### 6.1.1.2 Driving the ADC in DES Mode

The ADC12D1800 can be configured as either a 2-channel, 1.8 GSPS device (Non-DES Mode) or a 1-channel 3.6GSPS device (DES Mode). When the device is configured in DES Mode, there is a choice for with which input to drive the single-channel ADC. These are the 3 options:

DES – externally driving the I-channel input only. This is the default selection when the ADC is configured in DES Mode. It may also be referred to as "DESI" for added clarity.

DESQ - externally driving the Q-channel input only.

DESIQ – externally driving both the I- and Q-channel inputs. VinI+ and VinQ+ should be driven with the exact same signal. VinI- and VinQ- should be driven with the exact same signal, which is the differential complement to the one driving VinI+ and VinQ+.

The input impedance for each I- and Q-input is  $100\Omega$  differential (or  $50\Omega$  single-ended), so the trace to each VinI+, VinI-, VinQ+, and VinQ- should always be  $50\Omega$  single-ended. If a single I- or Q-input is being driven, then that input will present a  $100\Omega$  differential load. For example, if a  $50\Omega$  single-ended source is driving the ADC, then a 1:2 balun will transform the impedance to  $100\Omega$  differential. However, if the ADC is being driven in DESIQ Mode, then the  $100\Omega$  differential impedance from the I-input will appear in parallel with the Q-input for a composite load of  $50\Omega$  differential and a 1:1 balun would be appropriate. See Figure 6-1 for an example circuit driving the ADC in DESIQ Mode. A recommended part selection is using the Mini-Circuits TC1-1-13MA+ balun with Ccouple =  $0.22\mu$ F.

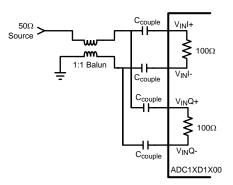


Figure 6-1. Driving DESIQ Mode

In the case that only one channel is used in Non-DES Mode or that the ADC is driven in DESI or DESQ Mode, the unused analog input should be terminated to reduce any noise coupling into the ADC. See Table 6-3 for details.

Table 6-3. Unused Analog Input Recommended Termination

MODE	POWER DOWN	COUPLING	RECOMMENDED TERMINATION
Non-DES	Yes	AC/DC	Tie Unused+ and Unused- to Vbg
DES/Non-DES	No	DC	Tie Unused+ and Unused- to Vbg
DES/Non-DES	No	AC	Tie Unused+ to Unused-



### 6.1.1.3 FSR and the Reference Voltage

The full-scale analog differential input range ( $V_{\rm IN\_FSR}$ ) of the ADC12D1800 is derived from an internal bandgap reference. In Non-ECM, this full-scale range must be set by the logic-high setting of the FSR Pin; see Section 5.5.1.1.9. The FSR Pin operates on both I- and Q-channels. In ECM, the full-scale range may be independently set for each channel via Addr:3h and Bh with 15 bits of precision; see Section 5.6.1. The best SNR is obtained with a higher full-scale input range, but better distortion and SFDR are obtained with a lower full-scale input range. It is not possible to use an external analog reference voltage to modify the full-scale range, and this adjustment should only be done digitally, as described.

A buffered version of the internal bandgap reference voltage is made available at the  $V_{BG}$  Pin for the user. The  $V_{BG}$  pin can drive a load of up to 80 pF and source or sink up to 100  $\mu$ A. It should be buffered if more current than this is required. This pin remains as a constant reference voltage regardless of what full-scale range is selected and may be used for a system reference.  $V_{BG}$  is a dual-purpose pin and it may also be used to select a higher LVDS output common-mode voltage; see Section 5.5.1.1.11.

### 6.1.1.4 Out-of-Range Indication

Differential input signals are digitized to 12 bits, based on the full-scale range. Signal excursions beyond the full-scale range, i.e. greater than  $+V_{IN\_FSR}/2$  or less than  $+V_{IN\_FSR}/2$ , will be clipped at the output. An input signal which is above the FSR will result in all 1's at the output and an input signal which is below the FSR will result in all 0's at the output. When the conversion result is clipped for the I-channel input, the Out-of-Range I-channel (ORI) output is activated such that ORI+ goes high and ORI- goes low while the signal is out of range. This output is active as long as accurate data on either or both of the buses would be outside the range of 000h to FFFh. The Q-channel has a separate ORQ which functions similarly.

# 6.1.1.5 Maximum Input Range

The recommended operating and absolute maximum input range may be found in Section 4.3 and Section 4.1, respectively. Under the stated allowed operating conditions, each Vin+ and Vin- input pin may be operated in the range from 0V to 2.15V if the input is a continuous 100% duty cycle signal and from 0V to 2.5V if the input is a 10% duty cycle signal. The absolute maximum input range for Vin+ and Vin- is from -0.15V to 2.5V. These limits apply only for input signals for which the input common mode voltage is properly maintained.

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### 6.1.1.6 AC-Coupled Input Signals

The ADC12D1800 analog inputs require a precise common-mode voltage. This voltage is generated onchip when AC-coupling Mode is selected. See Section 5.5.1.1.10 for more information about how to select AC-coupled Mode.

In AC-coupled Mode, the analog inputs must of course be AC-coupled. For an ADC12D1800 used in a typical application, this may be accomplished by on-board capacitors, as shown in Figure 6-2. For the ADC12D1800RB, the SMA inputs on the Reference Board are directly connected to the analog inputs on the ADC12D1800, so this may be accomplished by DC blocks (included with the hardware kit).

When the AC-coupled Mode is selected, an analog input channel that is not used (e.g. in DES Mode) should be connected to AC ground, e.g. through capacitors to ground. Do not connect an unused analog input directly to ground.

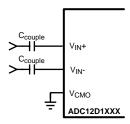


Figure 6-2. AC-coupled Differential Input

The analog inputs for the ADC12D1800 are internally buffered, which simplifies the task of driving these inputs and the RC pole which is generally used at sampling ADC inputs is not required. If the user desires to place an amplifier circuit before the ADC, care should be taken to choose an amplifier with adequate noise and distortion performance, and adequate gain at the frequencies used for the application.

# 6.1.1.7 DC-Coupled Input Signals

In DC-coupled Mode, the ADC12D1800 differential inputs must have the correct common-mode voltage. This voltage is provided by the device itself at the  $V_{CMO}$  output pin. It is recommended to use this voltage because the  $V_{CMO}$  output potential will change with temperature and the common-mode voltage of the driving device should track this change. Full-scale distortion performance falls off as the input common mode voltage deviates from  $V_{CMO}$ . Therefore, it is recommended to keep the input common-mode voltage within 100 mV of  $V_{CMO}$  (typical), although this range may be extended to  $\pm 150$  mV (maximum). See  $V_{CMI}$  in Section 4.7 and ENOB vs.  $V_{CMI}$  in Section 4.16. Performance in AC- and DC-coupled Mode are similar, provided that the input common mode voltage at both analog inputs remains within 100 mV of  $V_{CMO}$ .

# 6.1.1.8 Single-Ended Input Signals

The analog inputs of the ADC12D1800 are not designed to accept single-ended signals. The best way to handle single-ended signals is to first convert them to differential signals before presenting them to the ADC. The easiest way to accomplish single-ended to differential signal conversion is with an appropriate balun-transformer, as shown in Figure 6-3.

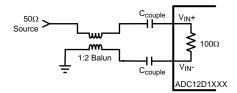


Figure 6-3. Single-Ended to Differential Conversion Using a Balun

When selecting a balun, it is important to understand the input architecture of the ADC. The impedance of the analog source should be matched to the ADC12D1800's on-chip  $100\Omega$  differential input termination resistor. The range of this termination resistor is specified as  $R_{IN}$  in Section 4.7.

# 6.1.2 Clock Inputs

The ADC12D1800 has a differential clock input, CLK+ and CLK-, which must be driven with an AC-coupled, differential clock signal. This provides the level shifting necessary to allow for the clock to be driven with LVDS, PECL, LVPECL, or CML levels. The clock inputs are internally terminated to  $100\Omega$  differential and self-biased. This section covers coupling, frequency range, level, duty-cycle, jitter, and layout considerations.

### 6.1.2.1 CLK Coupling

The clock inputs of the ADC12D1800 must be capacitively coupled to the clock pins as indicated in Figure 6-4.

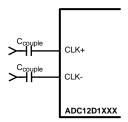


Figure 6-4. Differential Input Clock Connection

The choice of capacitor value will depend on the clock frequency, capacitor component characteristics and other system economic factors. For example, on the ADC12D1800RB, the capacitors have the value  $C_{couple} = 4.7$  nF which yields a high pass cutoff frequency,  $f_c = 677.2$  kHz.

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#### 6.1.2.2 CLK Frequency

Although the ADC12D1800 is tested and its performance is specified with a differential 1.8 GHz sampling clock, it will typically function well over the input clock frequency range; see  $f_{CLK}(min)$  and  $f_{CLK}(max)$  in Section 4.13. Operation up to  $f_{CLK}(max)$  is possible if the maximum ambient temperatures indicated are not exceeded. Operating at sample rates above  $f_{CLK}(max)$  for the maximum ambient temperature may result in reduced device reliability and product lifetime. This is due to the fact that higher sample rates results in higher power consumption and die temperatures. If  $f_{CLK} < 300$  MHz, enable LFS in the Control Register (Addr: 0h, Bit 8).

#### 6.1.2.3 CLK Level

The input clock amplitude is specified as  $V_{IN\_CLK}$  in Section 4.9. Input clock amplitudes above the max  $V_{IN\_CLK}$  may result in increased input offset voltage. This would cause the converter to produce an output code other than the expected 2047/2048 when both input pins are at the same potential. Insufficient input clock levels will result in poor dynamic performance. Both of these results may be avoided by keeping the clock input amplitude within the specified limits of  $V_{IN\_CLK}$ .

# 6.1.2.4 CLK Duty Cycle

The duty cycle of the input clock signal can affect the performance of any A/D converter. The ADC12D1800 features a duty cycle clock correction circuit which can maintain performance over the 20%-to-80% specified clock duty-cycle range. This feature is enabled by default and provides improved ADC clocking, especially in the Dual-Edge Sampling (DES) Mode.

#### 6.1.2.5 CLK Jitter

High speed, high performance ADCs such as the ADC12D1800 require a very stable input clock signal with minimum phase noise or jitter. ADC jitter requirements are defined by the ADC resolution (number of bits), maximum ADC input frequency and the input signal amplitude relative to the ADC input full scale range. The maximum jitter (the sum of the jitter from all sources) allowed to prevent a jitter-induced reduction in SNR is found to be

$$t_{J(MAX)} = (V_{IN(P-P)}/V_{FSR}) \times (1/(2^{(N+1)} \times \pi \times f_{IN}))$$
 (1)

where  $t_{J(MAX)}$  is the rms total of all jitter sources in seconds,  $V_{IN(P-P)}$  is the peak-to-peak analog input signal,  $V_{FSR}$  is the full-scale range of the ADC, "N" is the ADC resolution in bits and  $f_{IN}$  is the maximum input frequency, in Hertz, at the ADC analog input.

 $t_{J(MAX)}$  is the square root of the sum of the squares (RSS) sum of the jitter from all sources, including: the ADC input clock, system, input signals and the ADC itself. Since the effective jitter added by the ADC is beyond user control, it is recommended to keep the sum of all other externally added jitter to a minimum.

#### 6.1.2.6 CLK Layout

The ADC12D1800 clock input is internally terminated with a trimmed  $100\Omega$  resistor. The differential input clock line pair should have a characteristic impedance of  $100\Omega$  and (when using a balun), be terminated at the clock source in that  $(100\Omega)$  characteristic impedance.

It is good practice to keep the ADC input clock line as short as possible, tightly coupled, keep it well away from any other signals, and treat it as a transmission line. Otherwise, other signals can introduce jitter into the input clock signal. Also, the clock signal can introduce noise into the analog path if it is not properly isolated.

# 6.1.3 LVDS Outputs

The Data, ORI, ORQ, DCLKI and DCLKQ outputs are LVDS. The electrical specifications of the LVDS outputs are compatible with typical LVDS receivers available on ASIC and FPGA chips; but they are not IEEE or ANSI communications standards compliant due to the low +1.9V supply used on this chip. These outputs should be terminated with a  $100\Omega$  differential resistor placed as closely to the receiver as possible. If the  $100\Omega$  differential resistor is built in to the receiver, then an externally placed resistor is not necessary. This section covers common-mode and differential voltage, and data rate.

### 6.1.3.1 Common-mode and Differential Voltage

The LVDS outputs have selectable common-mode and differential voltage,  $V_{OS}$  and  $V_{OD}$ ; see Section 4.11. See Section 5.3.2 for more information.

Selecting the higher  $V_{OS}$  will also increase  $V_{OD}$  slightly. The differential voltage,  $V_{OD}$ , may be selected for the higher or lower value. For short LVDS lines and low noise systems, satisfactory performance may be realized with the lower  $V_{OD}$ . This will also result in lower power consumption. If the LVDS lines are long and/or the system in which the ADC12D1800 is used is noisy, it may be necessary to select the higher  $V_{OD}$ .

#### 6.1.3.2 Output Data Rate

The data is produced at the output at the same rate it is sampled at the input. The minimum recommended input clock rate for this device is  $f_{\text{CLK(MIN)}}$ ; see Section 4.13. However, it is possible to operate the device in 1:2 Demux Mode and capture data from just one 12-bit bus, e.g. just DI (or DId) although both DI and DId are fully operational. This will decimate the data by two and effectively halve the data rate.

#### 6.1.3.3 Terminating Unused LVDS Output Pins

If the ADC is used in Non-Demux Mode, then only the DI and DQ data outputs will have valid data present on them. The DId and DQd data outputs may be left not connected; if unused, they are internally at TRI-STATE.

Similarly, if the Q-channel is powered-down (i.e. PDQ is logic-high), the DQ data output pins, DCLKQ and ORQ may be left not connected.

#### 6.1.4 Synchronizing Multiple ADC12D1800S in a System

The ADC12D1800 has two features to assist the user with synchronizing multiple ADCs in a system; AutoSync and DCLK Reset. The AutoSync feature and designates one ADC12D1800 as the Master ADC and other ADC12D1800s in the system as Slave ADCs. The DCLK Reset feature performs the same function as the AutoSync feature, but is the first generation solution to synchronizing multiple ADCs in a system; it is disabled by default. For the application in which there are multiple Master and Slave ADC12D1800s in a system, AutoSync may be used to synchronize the Slave ADC12D1800(s) to each respective Master ADC12D1800 and the DCLK Reset may be used to synchronize the Master ADC12D1800s to each other.

If the AutoSync or DCLK Reset feature is not used, see Table 6-4 for recommendations about terminating unused pins.

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Table 6-4. Unused AutoSync and DCLK Reset Pin Recommendation

PINS	UNUSED TERMINATION
RCLK+/-	Do not connect.
RCOUT1+/-	Do not connect.
RCOUT2+/-	Do not connect.
DCLK_RST+	Connect to GND via 1kΩ resistor.
DCLK_RST-	Connect to $V_A$ via $1k\Omega$ resistor.

# 6.1.4.1 AutoSync Feature

AutoSync is a feature which continuously synchronizes the outputs of multiple ADC12D1800s in a system. It may be used to synchronize the DCLK and data outputs of one or more Slave ADC12D1800s to one Master ADC12D1800. Several advantages of this feature include: no special synchronization pulse required, any upset in synchronization is recovered upon the next DCLK cycle, and the Master/Slave ADC12D1800s may be arranged as a binary tree so that any upset will quickly propagate out of the system.

An example system is shown below in Figure 6-5 which consists of one Master ADC and two Slave ADCs. For simplicity, only one DCLK is shown; in reality, there is DCLKI and DCLKQ, but they are always in phase with one another.

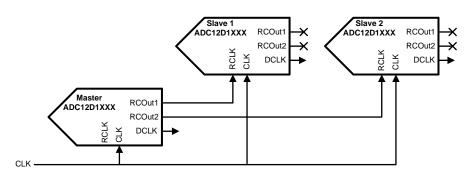


Figure 6-5. AutoSync Example

In order to synchronize the DCLK (and Data) outputs of multiple ADCs, the DCLKs must transition at the same time, as well as be in phase with one another. The DCLK at each ADC is generated from the CLK after some latency, plus  $t_{\text{OD}}$  minus  $t_{\text{AD}}$ . Therefore, in order for the DCLKs to transition at the same time, the CLK signal must reach each ADC at the same time. To tune out any differences in the CLK path to each ADC, the  $t_{\text{AD}}$  adjust feature may be used. However, using the  $t_{\text{AD}}$  adjust feature will also affect when the DCLK is produced at the output. If the device is in Demux Mode, then there are four possible phases which each DCLK may be generated on because the typical CLK = 1GHz and DCLK = 250 MHz for this case. The RCLK signal controls the phase of the DCLK, so that each Slave DCLK is on the same phase as the Master DCLK.

The AutoSync feature may only be used via the Control Registers. For more information, see AN-2132 (SNAA073).

#### 6.1.4.2 DCLK Reset Feature

The DCLK reset feature is available via ECM, but it is disabled by default. DCLKI and DCLKQ are always synchronized, by design, and do not require a pulse from DCLK\_RST to become synchronized.

The DCLK\_RST signal must observe certain timing requirements, which are shown in Figure 4-6 of the Timing Diagrams. The DCLK\_RST pulse must be of a minimum width and its deassertion edge must observe setup and hold times with respect to the CLK input rising edge. These timing specifications are listed as t<sub>PWR</sub>, t<sub>SR</sub> and t<sub>HR</sub> and may be found in Section 4.13.

The DCLK\_RST signal can be asserted asynchronously to the input clock. If DCLK\_RST is asserted, the DCLK output is held in a designated state (logic-high) in Demux Mode; in Non-Demux Mode, the DCLK continues to function normally. Depending upon when the DCLK\_RST signal is asserted, there may be a narrow pulse on the DCLK line during this reset event. When the DCLK\_RST signal is de-asserted, there are  $t_{SYNC_DLY}$  CLK cycles of systematic delay and the next CLK rising edge synchronizes the DCLK output with those of other ADC12D1800s in the system. For 90° Mode (DDRPh = logic-high), the synchronizing edge occurs on the rising edge of CLK, 4 cycles after the first rising edge of CLK after DCLK\_RST is released. For 0° Mode (DDRPh = logic-low), this is 5 cycles instead. The DCLK output is enabled again after a constant delay of  $t_{OD}$ .

For both Demux and Non-Demux Modes, there is some uncertainty about how DCLK comes out of the reset state for the first DCLK\_RST pulse. For the second (and subsequent) DCLK\_RST pulses, the DCLK will come out of the reset state in a known way. Therefore, if using the DCLK Reset feature, it is recommended to apply one "dummy" DCLK\_RST pulse before using the second DCLK\_RST pulse to synchronize the outputs. This recommendation applies each time the device or channel is powered-on.

When using DCLK\_RST to synchronize multiple ADC12D1800s, it is required that the Select Phase bits in the Control Register (Addr: Eh, Bits 3,4) be the same for each Master ADC12D1800.

# 6.1.5 Recommended System Chips

TI recommends these other chips including temperature sensors, clocking devices, and amplifiers in order to support the ADC12D1800 in a system design.

# 6.1.5.1 Temperature Sensor

The ADC12D1800 has an on-die temperature diode connected to pins Tdiode+/- which may be used to monitor the die temperature. TI also provides a family of temperature sensors for this application which monitor different numbers of external devices, see Table 6-5.

**Table 6-5. Temperature Sensor Recommendation** 

NUMBER OF EXTERNAL DEVICES MONITORED	RECOMMENDED TEMPERATURE SENSOR
1	LM95235
2	LM95213
4	LM95214

The temperature sensor (LM95235/13/14) is an 11-bit digital temperature sensor with a 2-wire System Management Bus (SMBus) interface that can monitor the temperature of one, two, or four remote diodes as well as its own temperature. It can be used to accurately monitor the temperature of up to one, two, or four external devices such as the ADC12D1800, a FPGA, other system components, and the ambient temperature.



The temperature sensor reports temperature in two different formats for +127.875°C/-128°C range and 0°/255°C range. It has a Sigma-Delta ADC core which provides the first level of noise immunity. For improved performance in a noisy environment, the temperature sensor includes programmable digital filters for Remote Diode temperature readings. When the digital filters are invoked, the resolution for the Remote Diode readings increases to 0.03125°C. For maximum flexibility and best accuracy, the temperature sensor includes offset registers that allow calibration for other types of diodes.

Diode fault detection circuitry in the temperature sensor can detect the absence or fault state of a remote diode: whether D+ is shorted to the power supply, D- or ground, or floating.

In the following typical application, the LM95213 is used to monitor the temperature of an ADC12D1800 as well as an FPGA, see Figure 6-6. If this feature is unused, the Tdiode+/- pins may be left floating.

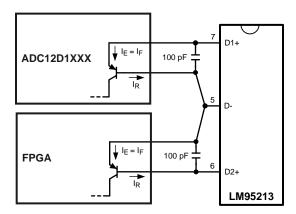


Figure 6-6. Typical Temperature Sensor Application

#### 6.1.5.2 Clocking Device

The clock source can be a PLL/VCO device such as the LMX2531LQxxxx family of products. The specific device should be selected according to the desired ADC sampling clock frequency. The ADC12D1800RB uses the LMX2531LQ1778E, with the ADC clock source provided by the Aux PLL output. Other devices which may be considered based on clock source, jitter cleaning, and distribution purposes are the LMK01XXX, LMK02XXX, LMK03XXX and LMK04XXX product families.

#### 6.1.5.3 Amplifiers for Analog Input

The following amplifiers can be used for ADC12D1800 applications which require DC coupled input or signal gain, neither of which can be provided with a transformer coupled input circuit. In addition, several of the amplifiers provide single ended to differential conversion options:

AMPLIFIER	BANDWIDTH	BRIEF FEATURES
LMH3401	7 GHz	Fixed gain, single ended to differential conversion
LMH5401	8 GHz	Configurable Gain, single ended to differential conversion
LMH6401	4.5 GHz	Digital Variable Controlled Gain
LMH6554	2.8 GHz	Configurable gain

Fixed gain

1.2 GHz

Table 6-6. Amplifier Recommendation

LMH6555

# 6.1.5.4 Balun Recommendations for Analog Input

The following baluns are recommended for the ADC12D1800 for applications which require no gain. When evaluating a balun for the application of driving an ADC, some important qualities to consider are phase error and magnitude error.

Table 6-7. Balun Recommendations

BALUN	BANDWIDTH
Mini-Circuits TC1-1-13MA+	4.5 - 3000 MHz
Anaren B0430J50100A00	400 - 3000 MHz
Mini-Circuits ADTL2-18	30 - 1800 MHz

# 6.2 Typical Application

The ADC12D1800 can be used to directly sample a signal in the RF frequency range for downstream processing. The wide input bandwidth, buffered input, high sampling rate and make ADC12D1800 ideal for RF sampling applications.

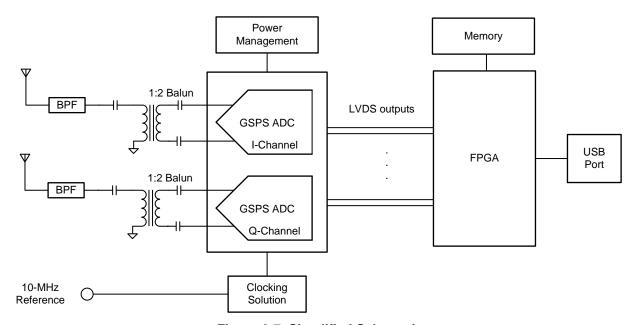


Figure 6-7. Simplified Schematic



# 6.2.1 Design Requirements

In this example ADC12D1800 will be used to sample signals in DES mode and Non-Des mode. The design parameters are listed Table 6-8.

Table 6-8. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUES (NON-DESI MODE)	EXAMPLE VALUES (DESI MODE)
Signal Center Frequency	2000 MHz	1125 MHz
Signal Bandwidth	100 MHz	400 MHz
ADC Sampling Rate	1800 MSPS	3600 MSPS
Signal Nominal Amplitude	–7 dBm	−7 dBm
Signal Maximum Amplitude	6 dBm	6 dBm
Minimum SNR (In BW of Interest)	46 dBc	46 dBc
Minimum THD (In BW of Interest)	-54 dBc	-61 dBc
Minimum SFDR (In BW of Interest)	53 dBc	53 dBc

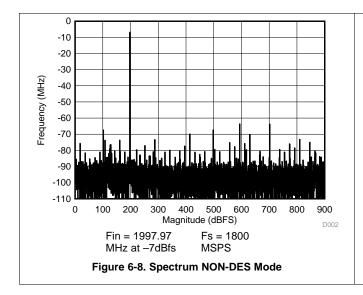
# 6.2.2 Detailed Design Procedure

Use the following steps to design the RF receiver:

- Select the appropriate mode of operation (DES mode or Non-DES mode).
- Use the input signal frequency to select an appropriate sampling rate.
- Select the sampling rate so that the input signal is within the Nyquist zone and away from any harmonics and interleaving tones.
- Select the system components such as clocking device, amplifier for analog input and Balun according to sampling frequency and input signal frequency.
- See Section 6.1.5.2 for the recommended clock sources.
- See Table 6-4 for recommended analog amplifiers.
- See Table 6-5 for recommended Balun components.
- Select the bandpass filters and limiter components based on the requirement to attenuate the unwanted input signals.

# 6.2.3 Application Curves

The following curves show an RF signal at 1997.97 MHz captured at a sample rate of 1800 MSPS in NON-DES mode and an RF signal at 1123.97 MHz sample at an effective sample rate of 3600 MSPS in DES mode.



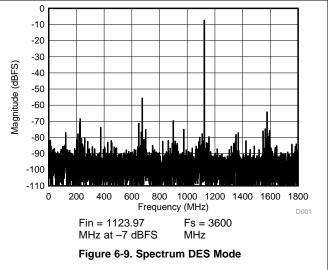


Table 6-9. ADC12D1800 Performance for Single Tone Signal at 1997.97 MHz in NON-DES Mode

PARAMETER	VALUE
SNR	47.9 dBc
SFDR	54.9 dBc
THD	−58.2 dBc
SINAD	47.5 dBc
ENOB	7.6 bits

Table 6-10. ADC12D1800 Performance for Single Tone Signal at 1123.97 MHz in DES Mode

PARAMETER	VALUE
SNR	47.7 dBc
SFDR	55.6 dBc
THD	-62.8 dBc
SINAD	47.6 dBc
ENOB	7.6 bits



# 7 Power Supply Recommendations

### 7.1 System Power-on Considerations

There are a couple important topics to consider associated with the system power-on event including configuration and calibration, and the Data Clock.

# 7.1.1 Power-on, Configuration, and Calibration

Following the application of power to the ADC12D1800, several events must take place before the output from the ADC12D1800 is valid and at full performance; at least one full calibration must be executed with the device configured in the desired mode.

Following the application of power to the ADC12D1800, there is a delay of  $t_{CalDly}$  and then the Power-on Calibration is executed. This is why it is recommended to set the CalDly Pin via an external pull-up or pull-down resistor. This ensured that the state of that input will be properly set at the same time that power is applied to the ADC and  $t_{CalDly}$  will be a known quantity. For the purpose of this section, it is assumed that CalDly is set as recommended.

The Control Bits or Pins must be set or written to configure the ADC12D1800 in the desired mode. This must take place via either Extended Control Mode or Non-ECM (Pin Control Mode) before subsequent calibrations will yield an output at full performance in that mode. Some examples of modes include DES/Non-DES Mode, Demux/Non-demux Mode, and Full-Scale Range.

The simplest case is when device is in Non-ECM and the Control Pins are set by pull-up/down resistors, see Figure 7-1. For this case, the settings to the Control Pins ramp concurrently to the ADC voltage. Following the delay of  $t_{CalDly}$  and the calibration execution time,  $t_{CAL}$ , the output of the ADC12D1800 is valid and at full performance. If it takes longer than  $t_{CalDly}$  for the system to stabilize at its operating temperature, it is recommended to execute an on-command calibration at that time.

Another case is when the FPGA configures the Control Pins (Non-ECM) or writes to the SPI (ECM), see Figure 7-2. It is always necessary to comply with the Section 4.3 and Section 4.1; for example, the Control Pins may not be driven below the ground or above the supply, regardless of what the voltage currently applied to the supply is. Therefore, it is not recommended to write to the Control Pins or SPI before power is applied to the ADC12D1800. As long as the FPGA has completed writing to the Control Pins or SPI, the Power-on Calibration will result in a valid output at full performance. Once again, if it takes longer than  $t_{CalDly}$  for the system to stabilize at its operating temperature, it is recommended to execute an oncommand calibration at that time.

Due to system requirements, it may not be possible for the FPGA to write to the Control Pins or SPI before the Power-on Calibration takes place, see Figure 7-3. It is not critical to configure the device before the Power-on Calibration, but it is critical to realize that the output for such a case is not at its full performance. Following an On-command Calibration, the device will be at its full performance.

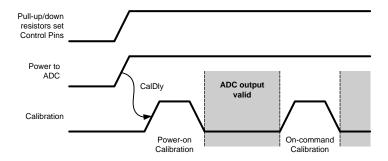


Figure 7-1. Power-on with Control Pins set by Pull-up/down Resistors

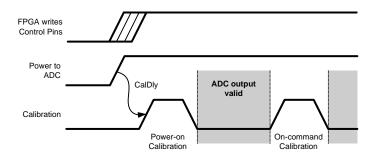


Figure 7-2. Power-on with Control Pins set by FPGA pre Power-on Cal

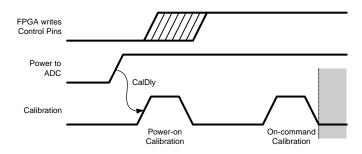


Figure 7-3. Power-on with Control Pins set by FPGA post Power-on Cal

# 7.1.2 Power-on and Data Clock (DCLK)

Many applications use the DCLK output for a system clock. For the ADC12D1800, each I- and Q-channel has its own DCLKI and DCLKQ, respectively. The DCLK output is always active, unless that channel is powered-down or the DCLK Reset feature is used while the device is in Demux Mode. As the supply to the ADC12D1800 ramps, the DCLK also comes up, see this example from the ADC12D1800RB: Figure 7-4. While the supply is too low, there is no output at DCLK. As the supply continues to ramp, DCLK functions intermittently with irregular frequency, but the amplitude continues to track with the supply. Much below the low end of operating supply range of the ADC12D1800, the DCLK is already fully operational.

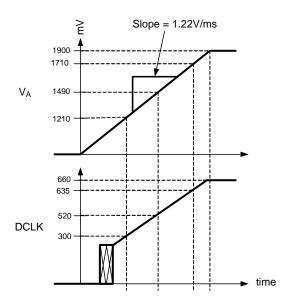


Figure 7-4. Supply and DCLK Ramping



# 8 Layout

# 8.1 Layout Guidelines

#### 8.1.1 Power Planes

All supply buses for the ADC should be sourced from a common linear voltage regulator. This ensures that all power buses to the ADC are turned on and off simultaneously. This single source will be split into individual sections of the power plane, with individual decoupling and connection to the different power supply buses of the ADC. Due to the low voltage but relatively high supply current requirement, the optimal solution may be to use a switching regulator to provide an intermediate low voltage, which is then regulated down to the final ADC supply voltage by a linear regulator. Please refer to the documentation provided for the ADC12D1800RB for additional details on specific regulators that are recommended for this configuration.

Power for the ADC should be provided through a broad plane which is located on one layer adjacent to the ground plane(s). Placing the power and ground planes on adjacent layers will provide low impedance decoupling of the ADC supplies, especially at higher frequencies. The output of a linear regulator should feed into the power plane through a low impedance multi-via connection. The power plane should be split into individual power peninsulas near the ADC. Each peninsula should feed a particular power bus on the ADC, with decoupling for that power bus connecting the peninsula to the ground plane near each power/ground pin pair. Using this technique can be difficult on many printed circuit CAD tools. To work around this, zero ohm resistors can be used to connect the power source net to the individual nets for the different ADC power buses. As a final step, the zero ohm resistors can be removed and the plane and peninsulas can be connected manually after all other error checking is completed.

# 8.1.2 Bypass Capacitors

The general recommendation is to have one 100nF capacitor for each power/ground pin pair. The capacitors should be surface mount multi-layer ceramic chip capacitors similar to Panasonic part number ECJ-0EB1A104K.

#### 8.1.3 Ground Planes

Grounding should be done using continuous full ground planes to minimize the impedance for all ground return paths, and provide the shortest possible image/return path for all signal traces.

# 8.1.4 Power System Example

The ADC12D1800RB uses continuous ground planes (except where clear areas are needed to provide appropriate impedance management for specific signals), see Figure 8-1. Power is provided on one plane, with the 1.9V ADC supply being split into multiple zones or peninsulas for the specific power buses of the ADC. Decoupling capacitors are connected between these power bus peninsulas and the adjacent ground planes using vias. The capacitors are located as close to the individual power/ground pin pairs of the ADC as possible. In most cases, this means the capacitors are located on the opposite side of the PCB to the ADC.

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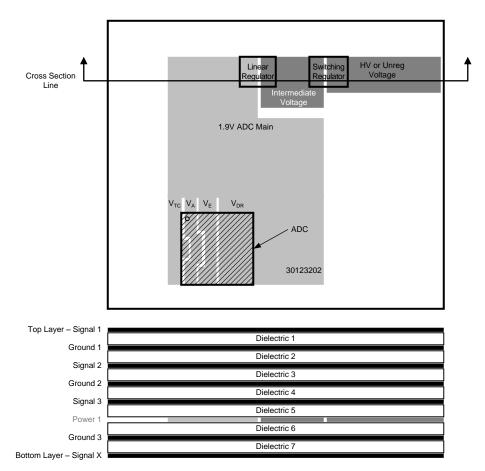


Figure 8-1. Power and Grounding Example

# 8.2 Layout Example

The following examples show layout-example plots. Figure 6-15 show a typical stack up for a 10 layer board.

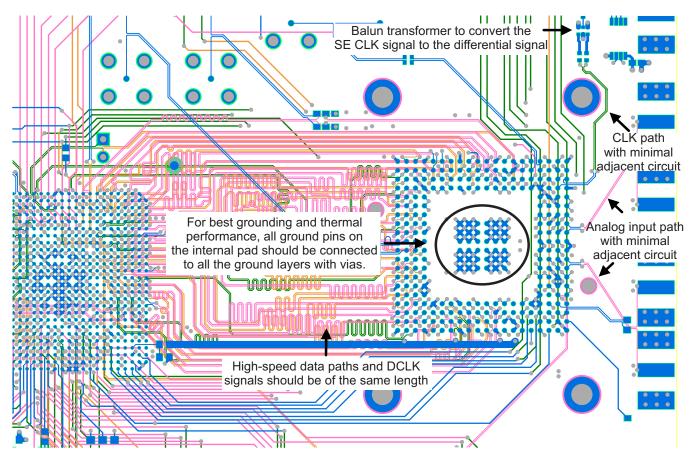


Figure 8-2. ADC12D1800RF Layout Example 1 - Top side and inner layers



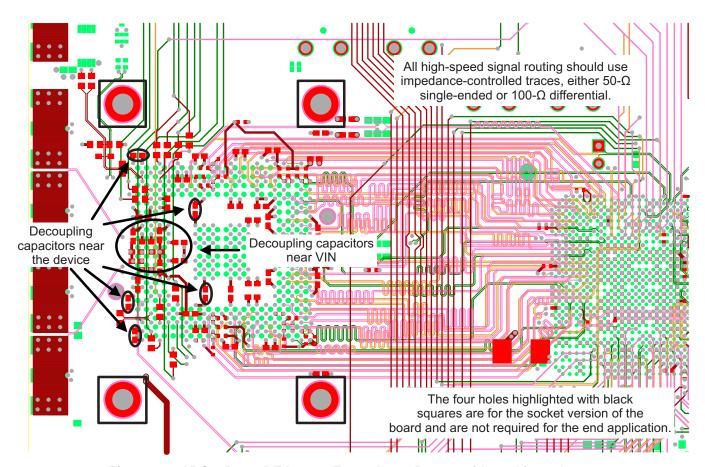
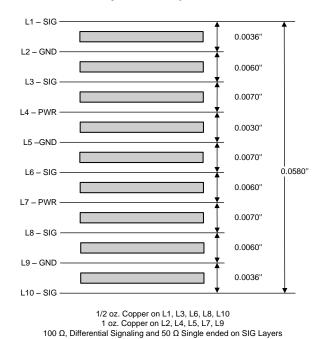


Figure 8-3. ADC12D1800RF Layout Example 1 – Bottom side and inner layers



Finished thickness 0.0620" including plating and solder mask

Figure 8-4. ADC12D1800RF Typical Stackup – 10 Layer Board

Low loss dielectric adjacent very high speed trace layers

# 8.3 Thermal Management

The Heat Slug Ball Grid Array (HSBGA) package is a modified version of the industry standard plastic BGA (Ball Grid Array) package. Inside the package, a copper heat spreader cap is attached to the substrate top with exposed metal in the center top area of the package. This results in a 20% improvement (typical) in thermal performance over the standard plastic BGA package.

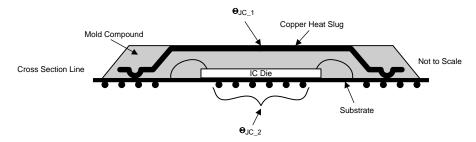


Figure 8-5. HSBGA Conceptual Drawing

The center balls are connected to the bottom of the die by vias in the package substrate, Figure 8-5. This gives a low thermal resistance between the die and these balls. Connecting these balls to the PCB ground planes with a low thermal resistance path is the best way dissipate the heat from the ADC. These pins should also be connected to the ground plane via a low impedance path for electrical purposes. The direct connection to the ground planes is an easy method to spread heat away from the ADC. Along with the ground plane, the parallel power planes will provide additional thermal dissipation.

The center ground balls should be soldered down to the recommended ball pads (See AN-1126 [SNOA021]). These balls will have wide traces which in turn have vias which connect to the internal ground planes, and a bottom ground pad/pour if possible. This ensures a good ground is provided for these balls, and that the optimal heat transfer will occur between these balls and the PCB ground planes.

In spite of these package enhancements, analysis using the standard JEDEC JESD51-7 four-layer PCB thermal model shows that ambient temperatures must be limited to a max of 65°C to ensure a safe operating junction temperature for the ADC12D1800. However, most applications using the ADC12D1800 will have a printed circuit board which is more complex than that used in JESD51-7. Typical circuit boards will have more layers than the JESD51-7 (eight or more), several of which will be used for ground and power planes. In those applications, the thermal resistance parameters of the ADC12D1800 and the circuit board can be used to determine the actual safe ambient operating temperature up to a maximum of 85°C.

Three key parameters are provided to allow for modeling and calculations. Because there are two main thermal paths between the ADC die and external environment, the thermal resistance for each of these paths is provided.  $\theta_{JC1}$  represents the thermal resistance between the die and the exposed metal area on the top of the HSBGA package.  $\theta_{JC2}$  represents the thermal resistance between the die and the center group of balls on the bottom of the HSBGA package. The final parameter is the allowed maximum junction temperature, which is  $T_{J}$ .

In other applications, a heat sink or other thermally conductive path can be added to the top of the HSBGA package to remove heat. In those cases,  $\theta_{JC1}$  can be used along with the thermal parameters for the heat sink or other thermal coupling added. Representative heat sinks which might be used with the ADC12D1800 include the Cool Innovations p/n 3-1212XXG and similar products from other vendors. In many applications, the printed circuit board will provide the primary thermal path conducting heat away from the ADC package. In those cases,  $\theta_{JC2}$  can be used in conjunction with printed circuit board thermal modeling software to determine the allowed operating conditions that will maintain the die temperature below the maximum allowable limit. Additional dissipation can be achieved by coupling a heat sink to the copper pour area on the bottom side of the printed circuit board.

Typically, dissipation will occur through one predominant thermal path. In these cases, the following calculations can be used to determine the maximum safe ambient operating temperature:

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$$T_J = T_A + P_D \times (\theta_{JC} + \theta_{CA})$$

$$T_J = T_A + P_{C(MAX)} \times (\theta_{JC} + \theta_{CA})$$

For  $\theta_{JC}$ , the value for the primary thermal path in the given application environment should be used ( $\theta_{JC1}$  or  $\theta_{JC2}$ ).  $\theta_{CA}$  is the thermal resistance from the case to ambient, which would typically be that of the heat sink used. Using this relationship and the desired ambient temperature, the required heat sink thermal resistance can be found. Alternately, the heat sink thermal resistance can be used to find the maximum ambient temperature. For more complex systems, thermal modeling software can be used to evaluate the printed circuit board system and determine the expected junction temperature given the total system dissipation and ambient temperature.

# 9 Device and Documentation Support

# 9.1 Device Support

# 9.1.1 Third-Party Products Disclaimer

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## 9.1.2 Specification Definitions

**APERTURE (SAMPLING) DELAY** is the amount of delay, measured from the sampling edge of the CLK input, after which the signal present at the input pin is sampled inside the device.

**APERTURE JITTER (t<sub>AJ</sub>)** is the variation in aperture delay from sample-to-sample. Aperture jitter can be effectively considered as noise at the input.

**CODE ERROR RATE (CER)** is the probability of error and is defined as the probable number of word errors on the ADC output per unit of time divided by the number of words seen in that amount of time. A CER of 10<sup>-18</sup> corresponds to a statistical error in one word about every 31.7 years.

**CLOCK DUTY CYCLE** is the ratio of the time that the clock waveform is at a logic high to the total time of one clock period.

**DIFFERENTIAL NON-LINEARITY (DNL)** is the measure of the maximum deviation from the ideal step size of 1 LSB. It is measured at the relevant sample rate,  $f_{CLK}$ , with  $f_{IN} = 1$ MHz sine wave.

**EFFECTIVE NUMBER OF BITS (ENOB, or EFFECTIVE BITS)** is another method of specifying Signal-to-Noise and Distortion Ratio, or SINAD. ENOB is defined as (SINAD – 1.76) / 6.02 and states that the converter is equivalent to a perfect ADC of this many (ENOB) number of bits.

**FULL POWER BANDWIDTH (FPBW)** is a measure of the frequency at which the reconstructed output fundamental drops to 3 dB below its low frequency value for a full-scale input.

**GAIN ERROR** is the deviation from the ideal slope of the transfer function. It can be calculated from Offset and Full-Scale Errors. The Positive Gain Error is the Offset Error minus the Positive Full-Scale Error. The Negative Gain Error is the Negative Full-Scale Error minus the Offset Error. The Gain Error is the Negative Full-Scale Error minus the Positive Full-Scale Error; it is also equal to the Positive Gain Error plus the Negative Gain Error.

**INTEGRAL NON-LINEARITY (INL)** is a measure of worst case deviation of the ADC transfer function from an ideal straight line drawn through the ADC transfer function. The deviation of any given code from this straight line is measured from the center of that code value step. The best fit method is used.

**INTERMODULATION DISTORTION (IMD)** is a measure of the near-in 3rd order distortion products  $(2f_2 - f_1, 2f_1 - f_2)$  which occur when two tones which are close in frequency  $(f_1, f_2)$  are applied to the ADC input. It is measured from the input tones level to the higher of the two distortion products (dBc) or simply the level of the higher of the two distortion products (dBFS). The input tones are typically -7dBFS.

LSB (LEAST SIGNIFICANT BIT) is the bit that has the smallest value or weight of all bits. This value is

 $V_{FS}/2^N$  (2)

where  $V_{FS}$  is the differential full-scale amplitude  $V_{IN\_FSR}$  as set by the FSR input and "N" is the ADC resolution in bits, which is 12 for the ADC12D1800.

**LOW VOLTAGE DIFFERENTIAL SIGNALING (LVDS) DIFFERENTIAL OUTPUT VOLTAGE (V<sub>ID</sub> and V<sub>OD</sub>)** is two times the absolute value of the difference between the V<sub>D</sub>+ and V<sub>D</sub>- signals; each signal measured with respect to Ground. V<sub>OD</sub> peak is V<sub>OD,P</sub>= (V<sub>D</sub>+ - V<sub>D</sub>-) and V<sub>OD</sub> peak-to-peak is V<sub>OD,P-P</sub>=  $2^*(V_D+ - V_D-)$ ; for this product, the V<sub>OD</sub> is measured peak-to-peak.

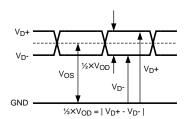


Figure 9-1. LVDS Output Signal Levels

**LVDS OUTPUT OFFSET VOLTAGE (V\_{OS})** is the midpoint between the D+ and D- pins output voltage with respect to ground; i.e.,  $[(V_D+) + (V_D-)]/2$ . See Figure 9-1.

**MISSING CODES** are those output codes that are skipped and will never appear at the ADC outputs. These codes cannot be reached with any input value.

MSB (MOST SIGNIFICANT BIT) is the bit that has the largest value or weight. Its value is one half of full scale.

**NEGATIVE FULL-SCALE ERROR (NFSE)** is a measure of how far the first code transition is from the ideal 1/2 LSB above a differential  $-V_{IN}/2$ . For the ADC12D1800 the reference voltage is assumed to be ideal, so this error is a combination of full-scale error and reference voltage error.

**NOISE FLOOR DENSITY** is a measure of the power density of the noise floor, expressed in dBFS/Hz and dBm/Hz. '0 dBFS' is defined as the power of a sinusoid which precisely used the full-scale range of the ADC.

**NOISE POWER RATIO (NPR)** is the ratio of the sum of the power outside the notched bins to the sum of the power in an equal number of bins inside the notch, expressed in dB.

**OFFSET ERROR (V<sub>OFF</sub>)** is a measure of how far the mid-scale point is from the ideal zero voltage differential input.

Offset Error = Actual Input causing average of 8k samples to result in an average code of 2047.5.

**OUTPUT DELAY (top)** is the time delay (in addition to Latency) after the rising edge of CLK+ before the data update is present at the output pins.

**OVER-RANGE RECOVERY TIME** is the time required after the differential input voltages goes from ±1.2V to 0V for the converter to recover and make a conversion with its rated accuracy.

**PIPELINE DELAY (LATENCY)** is the number of input clock cycles between initiation of conversion and when that data is presented to the output driver stage. The data lags the conversion by the Latency plus the  $t_{\rm OD}$ .

**POSITIVE FULL-SCALE ERROR (PFSE)** is a measure of how far the last code transition is from the ideal 1-1/2 LSB below a differential  $+V_{IN}/2$ . For the ADC12D1800 the reference voltage is assumed to be ideal, so this error is a combination of full-scale error and reference voltage error.



**SIGNAL TO NOISE RATIO (SNR)** is the ratio, expressed in dB, of the rms value of the fundamental for a single-tone to the rms value of the sum of all other spectral components below one-half the sampling frequency, not including harmonics or DC.

**SIGNAL TO NOISE PLUS DISTORTION (S/(N+D) or SINAD)** is the ratio, expressed in dB, of the rms value of the fundamental for a single-tone to the rms value of all of the other spectral components below half the input clock frequency, including harmonics but excluding DC.

**SPURIOUS-FREE DYNAMIC RANGE (SFDR)** is the difference, expressed in dB, between the rms values of the input signal at the output and the peak spurious signal, where a spurious signal is any signal present in the output spectrum that is not present at the input, excluding DC.

 $\theta_{JA}$  is the thermal resistance between the junction to ambient.

 $\theta_{JC1}$  represents the thermal resistance between the die and the exposed metal area on the top of the HSBGA package.

 $\theta_{\text{JC2}}$  represents the thermal resistance between the die and the center group of balls on the bottom of the HSBGA package.

**TOTAL HARMONIC DISTORTION (THD)** is the ratio expressed in dB, of the rms total of the first nine harmonic levels at the output to the level of the fundamental at the output. THD is calculated as

THD = 
$$20 \times \log \sqrt{\frac{A_{f2}^2 + \dots + A_{f10}^2}{A_{f1}^2}}$$
 (3)

where  $A_{f1}$  is the RMS power of the fundamental (output) frequency and  $A_{f2}$  through  $A_{f10}$  are the RMS power of the first 9 harmonic frequencies in the output spectrum.

- **Second Harmonic Distortion (2nd Harm)** is the difference, expressed in dB, between the RMS power in the input frequency seen at the output and the power in its 2nd harmonic level at the output.
- Third Harmonic Distortion (3rd Harm) is the difference expressed in dB between the RMS power in the input frequency seen at the output and the power in its 3rd harmonic level at the output.

## 9.2 Documentation Support

# 9.2.1 Related Documentation

For related documentation, see the following:

- AN-1126 BGA (Ball Grid Array), SNOA021
- AN-2132 Synchronizing Multiple GSPS ADCs in a System: The AutoSync Feature, SNAA073

## 9.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 9.4 Trademarks

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# 9.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# 9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

# 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
ADC12D1800CIUT	Active	Production	BGA (NXA)   292	40   JEDEC TRAY (10+1)	No	SNPB	Level-3-220C-168 HR	-40 to 85	ADC12D1800CIUT
ADC12D1800CIUT.A	Active	Production	BGA (NXA)   292	40   JEDEC TRAY (10+1)	No	SNPB	Level-3-220C-168 HR	-40 to 85	ADC12D1800CIUT
ADC12D1800CIUT/NO.A	Active	Production	BGA (NXA)   292	40   JEDEC TRAY (10+1)	Yes	SNAG	Level-3-250C-168 HR	-40 to 85	ADC12D1800CIUT
ADC12D1800CIUT/NOPB	Active	Production	BGA (NXA)   292	40   JEDEC TRAY (10+1)	Yes	SNAG	Level-3-250C-168 HR	-40 to 85	ADC12D1800CIUT

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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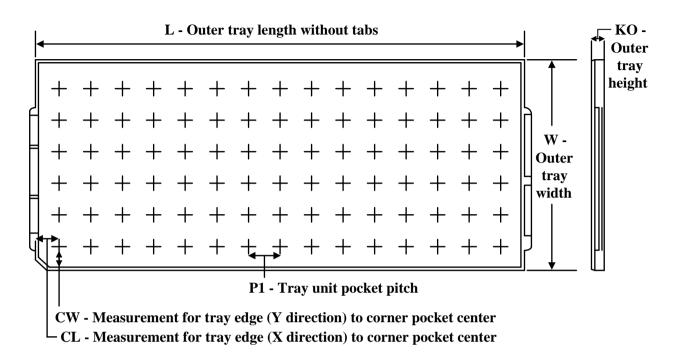
# **PACKAGE OPTION ADDENDUM**

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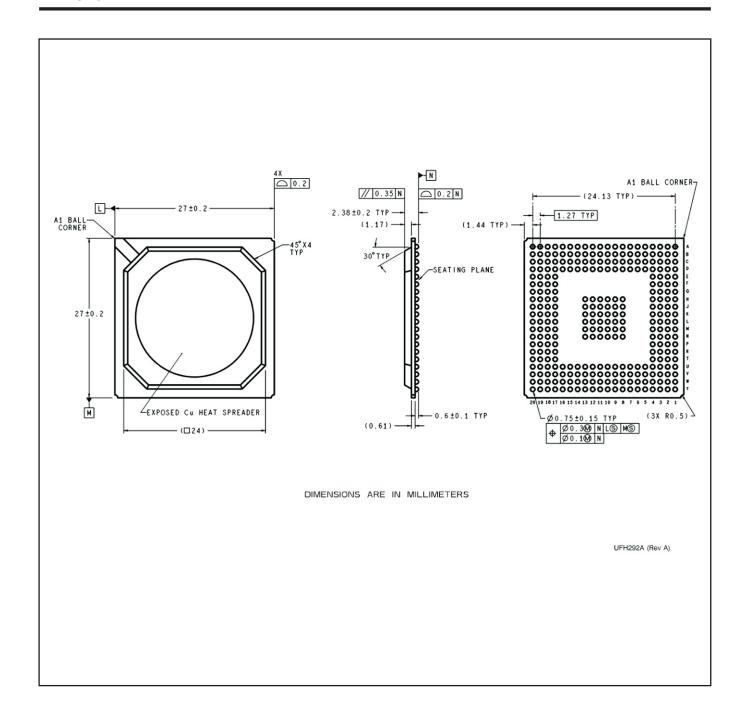
## **TRAY**



Chamfer on Tray corner indicates Pin 1 orientation of packed units.

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	Κ0 (μm)	P1 (mm)	CL (mm)	CW (mm)
ADC12D1800CIUT	NXA	BGA	292	40	4 X 10	150	322.6	135.9	7620	29.2	26.1	24.15
ADC12D1800CIUT.A	NXA	BGA	292	40	4 X 10	150	322.6	135.9	7620	29.2	26.1	24.15
ADC12D1800CIUT/ NO.A	NXA	BGA	292	40	4 X 10	150	322.6	135.9	7620	29.2	26.1	24.15
ADC12D1800CIUT/ NOPB	NXA	BGA	292	40	4 X 10	150	322.6	135.9	7620	29.2	26.1	24.15





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